

Excited Carrier Dynamics in Condensed Matter System

From ab initio simulation

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Back ground

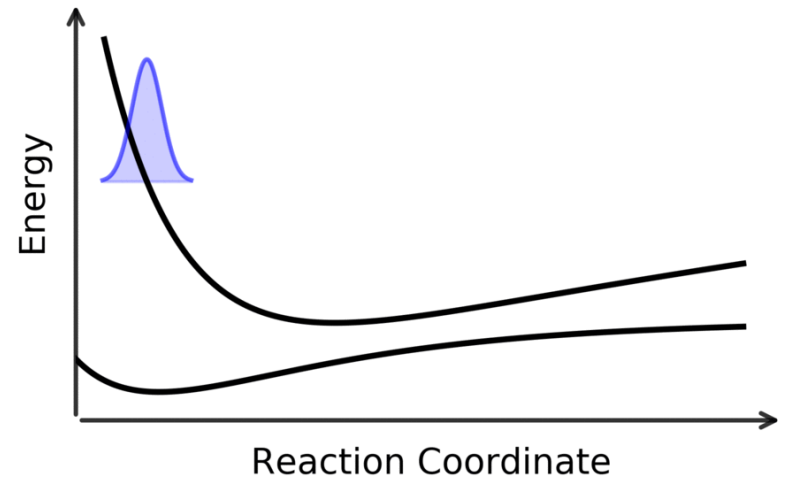
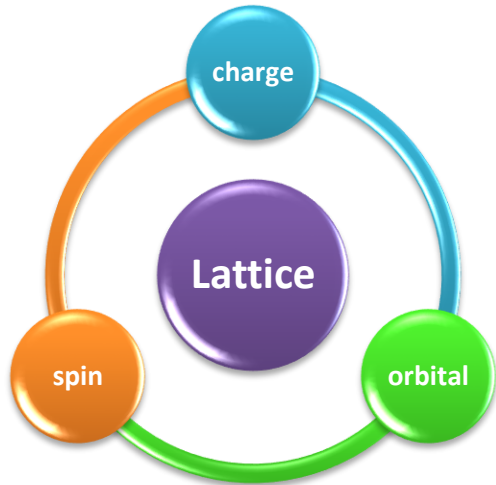
Single particle dynamics

Spin dynamics

Exciton Dynamics

Outlook

Carrier Dynamics in Condensed Matter Systems



Condensed matter physics: **Charge, spin and orbital**

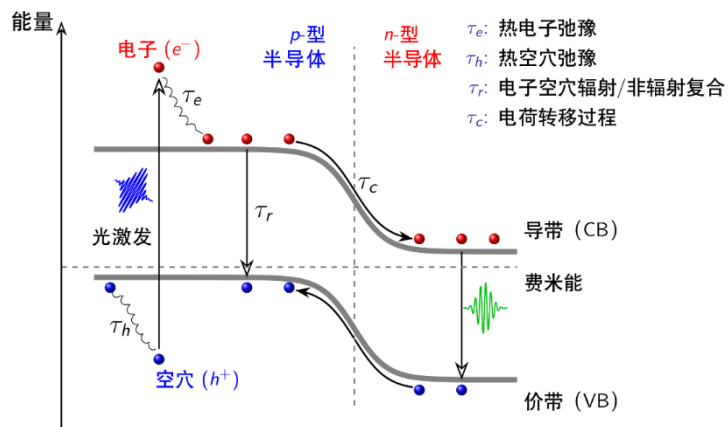
Important tool: **First principles calculations**

$$\mathcal{H}\psi = E\psi$$

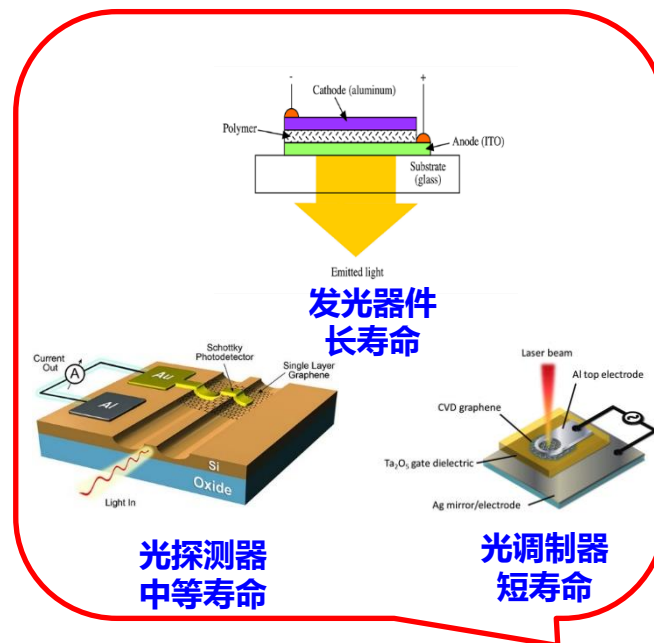
$$i\hbar \frac{\partial}{\partial t} \psi = \mathcal{H}\psi$$

Multi-dimension: **energy, momentum, real space, spin, time**

Applications of Photoexcited Carrier Dynamics



太阳能电池各种载流子动力学行为共同决定效率

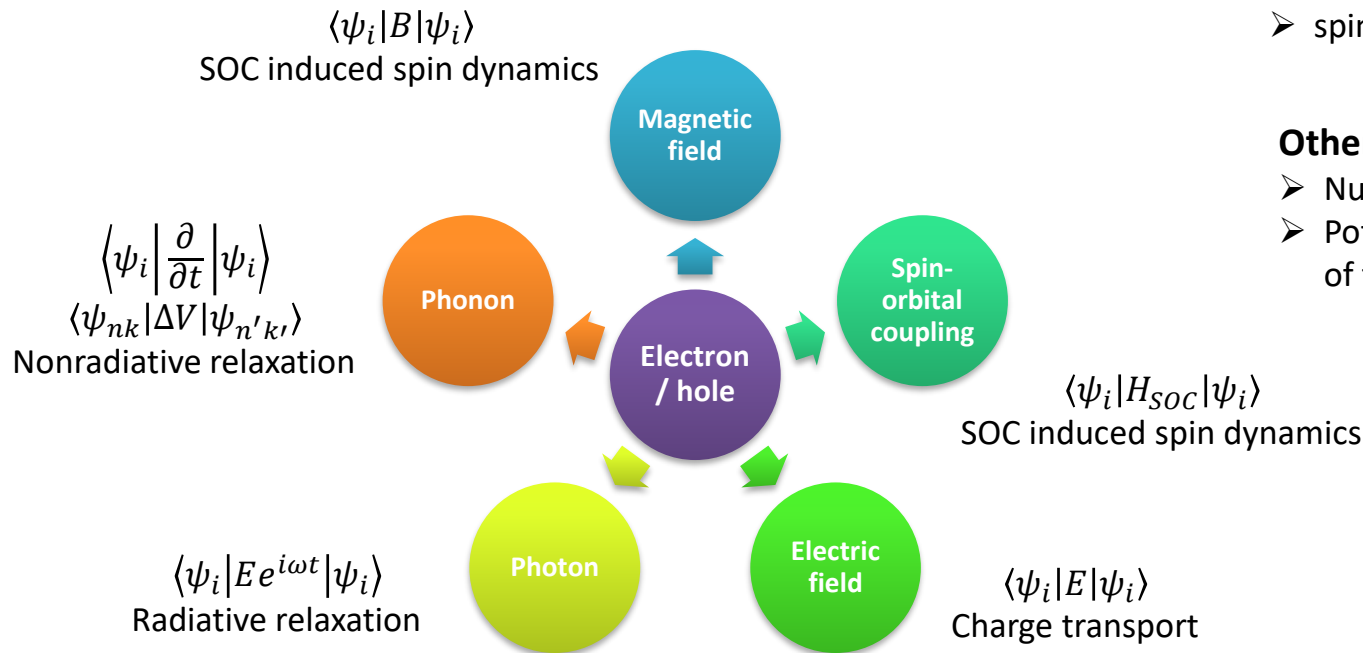


不同光电器件对材料载流子寿命有不同要求

Determining Factors of Carrier Dynamics

No perturbation, no relaxation : $\langle \psi_i | \psi_j \rangle = 0$

With perturbation:



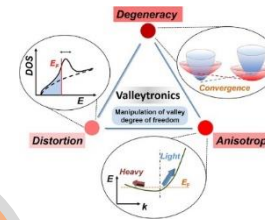
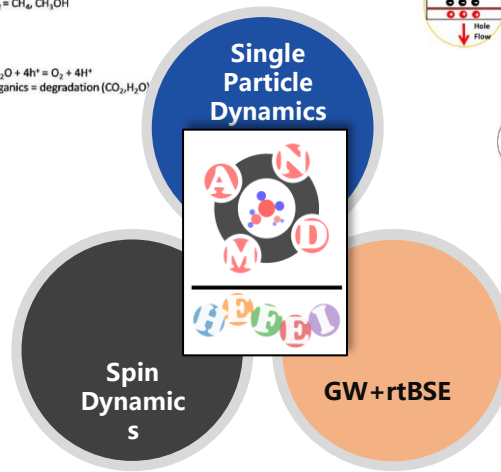
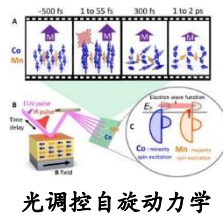
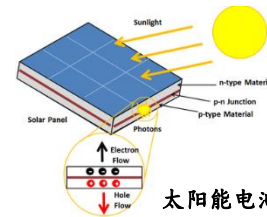
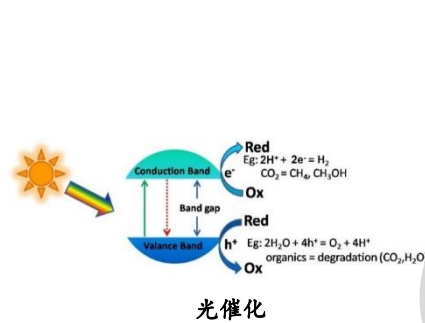
Many-body effects:

- e-e interaction
- e-h interaction (exciton effects)
- spin-spin interaction

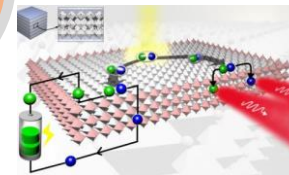
Other effects:

- Nuclear quantum effects
- Potential energy surface of the excited state

Ab initio Code for Excited Carrier Dynamics



谷电子学



Hefei-NAMD

Quantum decoherence

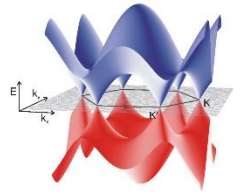
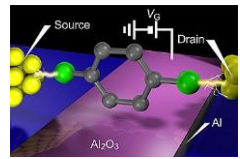
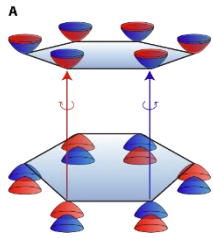
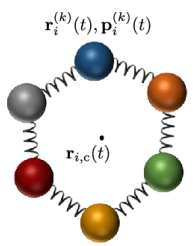
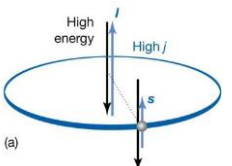
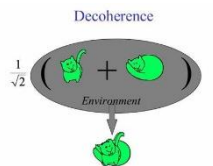
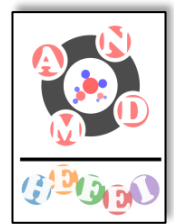
Spin-orbital Coupling

Nuclear Quantum effects

GW + real-time BSE

Charge transport

Dynamics in momentum space



2016

2018

2018

2018

2021

now

now



郑奇靖

褚维斌

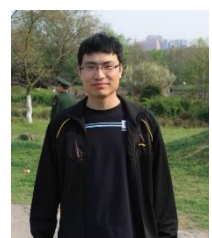
郑奇靖

褚维斌

蒋翔

田韞哲

郑镇法



赵传寓

史永亮

Back ground

Single particle dynamics

Spin dynamics

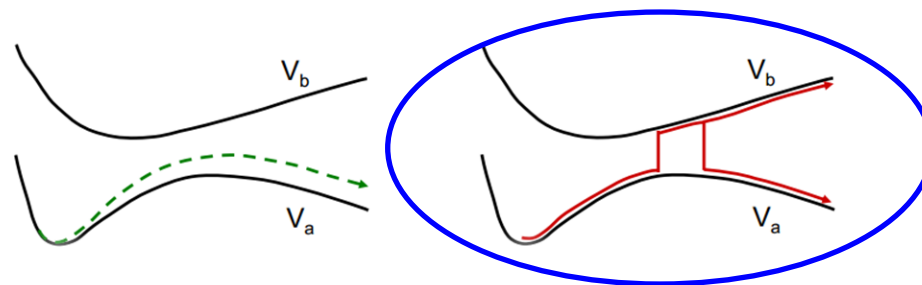
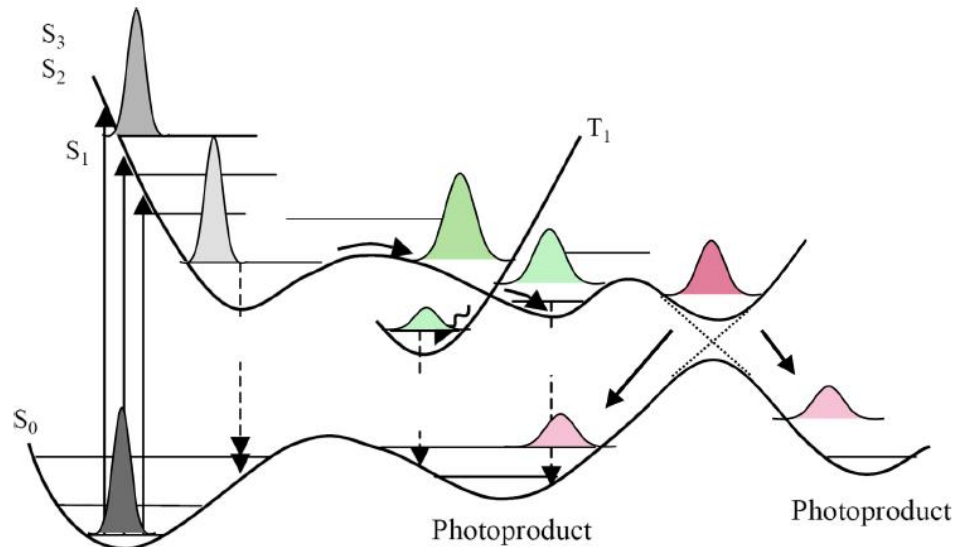
Exciton Dynamics

Outlook

Beyond Born-Oppenheimer Approximation

Mixed Quantum-Classical approximation

$$\Psi(\mathbf{r}, \mathbf{R}, t) = \Omega_j(\mathbf{R}, t)\Phi_j(\mathbf{r}; \mathbf{R}); \quad \hat{\mathcal{H}}_{el}(\mathbf{r}; \mathbf{R})\Phi_j(\mathbf{r}; \mathbf{R}) = E_j(\mathbf{R})\Phi_j(\mathbf{r}; \mathbf{R})$$



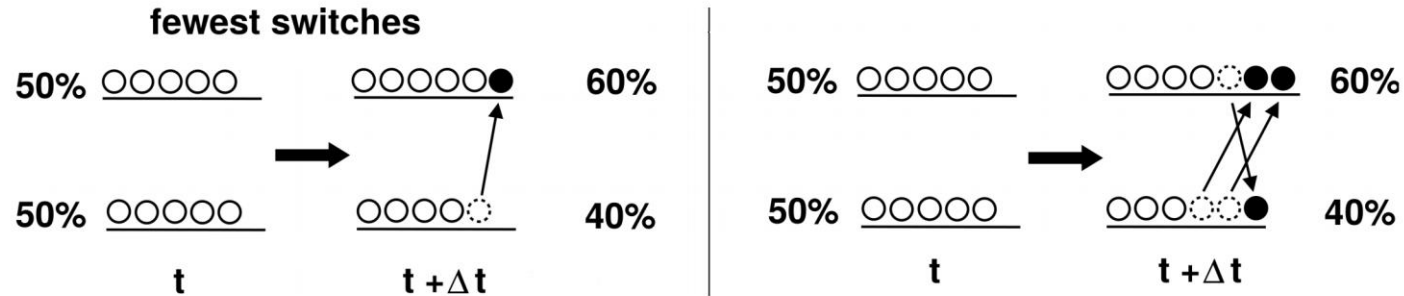
Ehrenfest Dynamics

Surface Hopping

$$M_\alpha \ddot{\mathbf{R}}_\alpha = -\nabla_\alpha \langle \hat{\mathcal{H}}_{el}(\mathbf{r}, \mathbf{R}) \rangle$$

$$M_\alpha \ddot{\mathbf{R}}_\alpha = -\nabla_\alpha E_k^{el}(\mathbf{R})$$

Fewest surface hopping



Assumptions

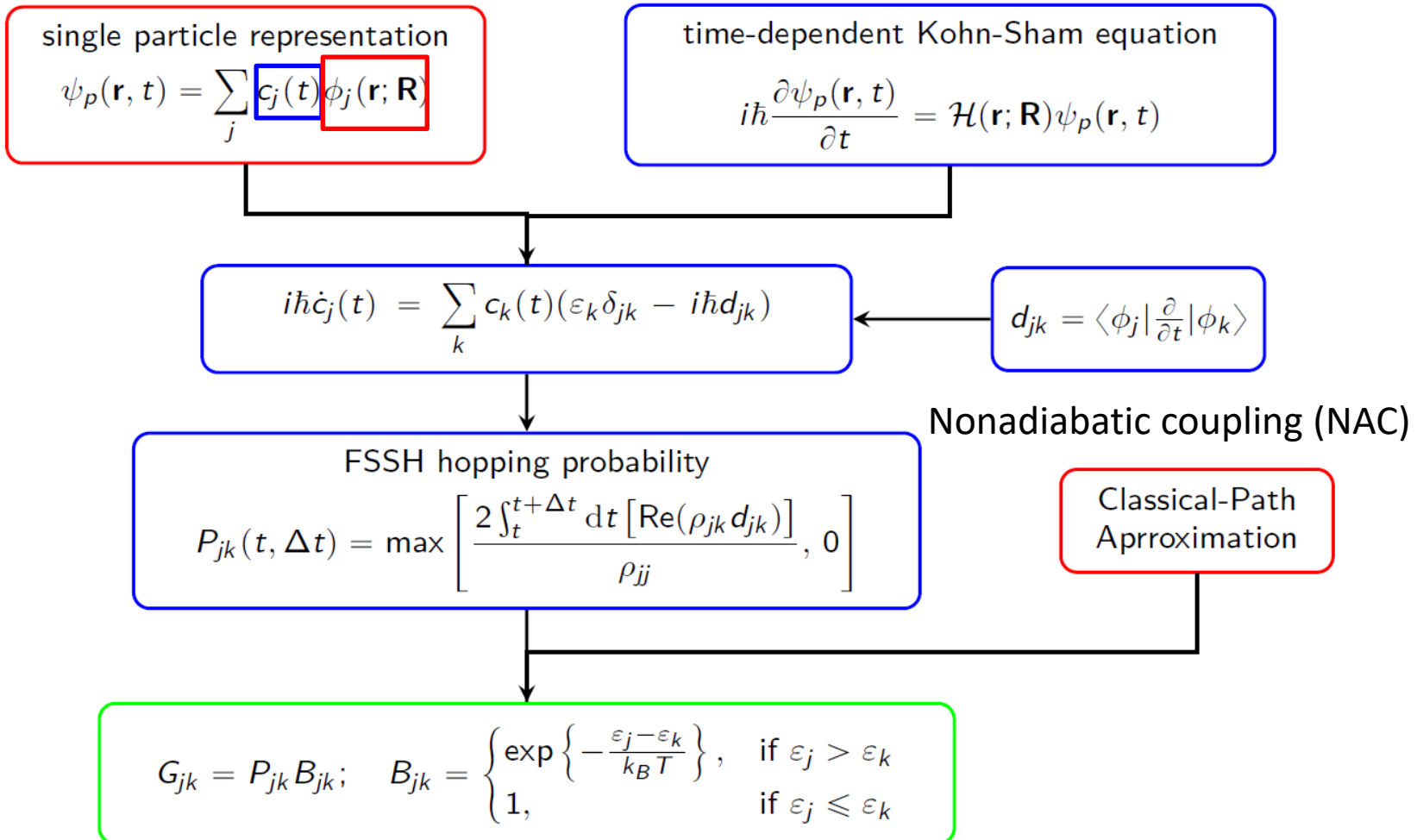
- Ensemble of independent trajectories have same coefficients $C_j(t)$.
- Internal consistency condition $N_j(t) \propto C_j^*(t) C_j(t) = \rho_{jj}(t)$.
- Hops from j to different $k \neq j$ are independent.
- Overall trajectory hops should be minimum.

Fewest-Switches: Hopping Probability

Transition from current state j to state $k \neq j$ is allowed only if population of state j is **decreasing**.

$$P_{jk}(t, \Delta t) = \max \left(- \frac{2 \int_t^{t+\Delta t} dt \left[\hbar^{-1} \text{Im}(\rho_{jk} H_{jk}) - \text{Re}(\rho_{jk} \mathbf{d}_{jk} \cdot \dot{\mathbf{R}}) \right]}{\rho_{jj}}, 0 \right)$$

Surface Hopping Combined with TDKS



A. Akimov and O. Prezhdo: Pyxaid

Q. Zheng, X. Jiang, et. al. J. Zhao: Hefei-NAMD

Electron-phonon interaction – Nonadiabatic coupling

$$H_{ki} = \epsilon_k \delta_{ik} - i\hbar \left\langle k \left| \frac{\partial}{\partial t} \right| i \right\rangle$$

Nonadiabatic coupling

$$d_{jk} = \left\langle \varphi_j \left| \frac{\partial}{\partial t} \right| \varphi_k \right\rangle$$
$$= \frac{\langle \varphi_j | \nabla_R H | \varphi_k \rangle}{\epsilon_k - \epsilon_j} \dot{R}$$

Electron-phonon matrix elements

$$\mathbf{d}_{jk} = \left\langle \phi_j \left| \frac{\partial}{\partial t} \right| \phi_k \right\rangle$$
$$= \frac{\langle \phi_j(t) | \phi_k(t + \Delta t) \rangle - \langle \phi_j(t + \Delta t) | \phi_k(t) \rangle}{2\Delta t}$$

- ✓ charge transfer dynamics
- ✓ Electron-hole recombination

Electron-phonon interaction - Decoherence Correction

退相干时间

纯退相时间（根据光响应理论）

$$D(t) = \exp(i\omega t) \left\langle -\frac{i}{\hbar} \int_0^t \Delta E d(\tau) t \right\rangle$$

能级差（右图一）

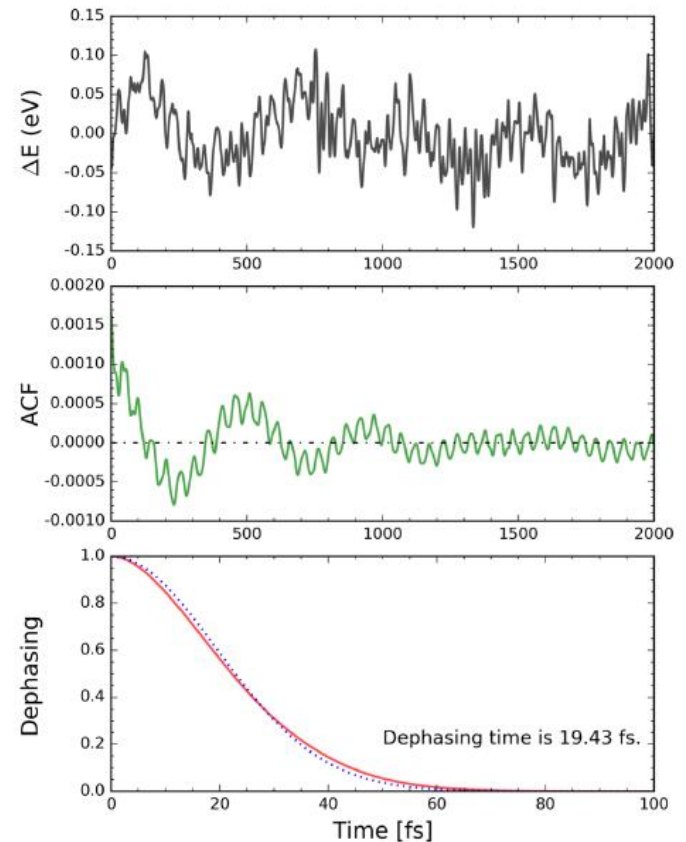
$$\Delta E = \Delta E_{ij} - \langle \Delta E_{ij} \rangle_T$$

自关联函数（右图二）

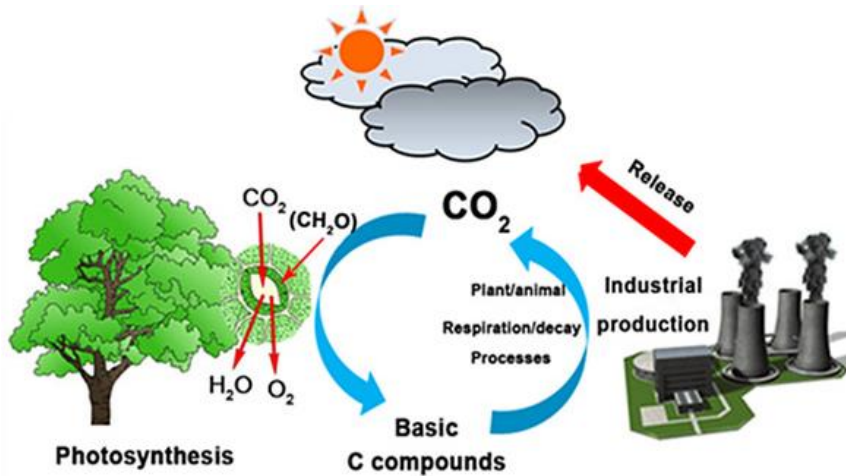
$$C(t) = \langle \Delta E(\tau) \Delta E(0) \rangle$$

退相干函数（二次卷积形式，右图三）

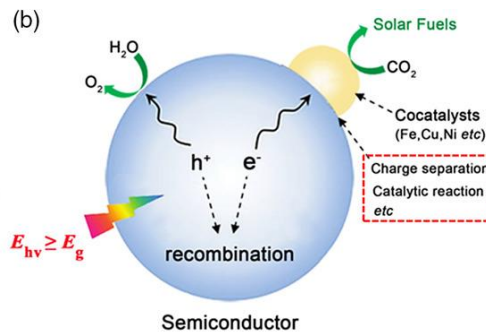
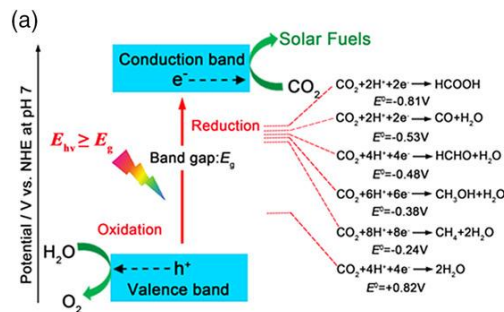
$$D(t) = \exp\left(-\frac{1}{\hbar^2} \int_0^t d\tau_1 \int_0^{\tau_1} d\tau_2 \langle \Delta E(\tau_1) \cdot \Delta E(\tau_2) \rangle\right)$$



What is Photocatalysis

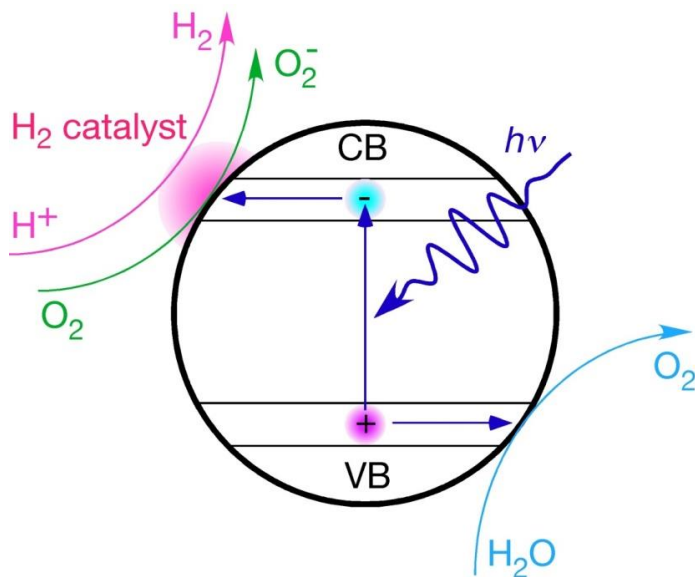


- ✓ 光解水
- ✓ 光还原 CO_2
- ✓ 降解污染物
- ...



目标：通过第一性原理计算理解光催化反应机制，提出理论设计提升反应效率

Crucial Processes in Photocatalysis on Surfaces



- ✓ **Photo-absorption**
absorption spectra (DFT, GW+BSE)
- ✓ **Photoexcited carrier trapping**
Lifetime of photoexcited carriers
Carrier migration to surface
Carrier trapping by molecules
- ✓ **Photochemical reaction on the surface**
Excited state reaction barrier

Crucial Processes in Photocatalysis on Surfaces

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absorption spectra (DFT, GW+BSE)

- ✓ **Photoexcited carrier trapping**

Lifetime of photoexcited carriers

Carrier migration to surface

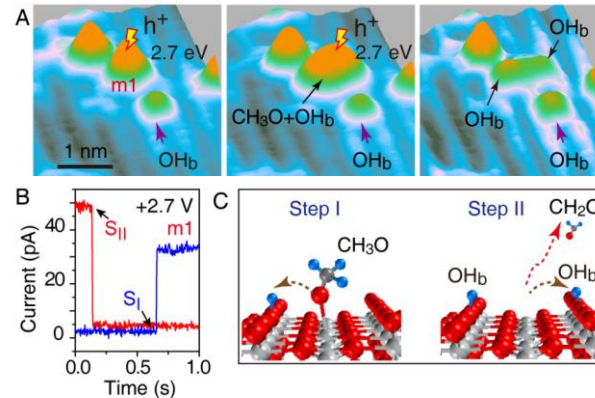
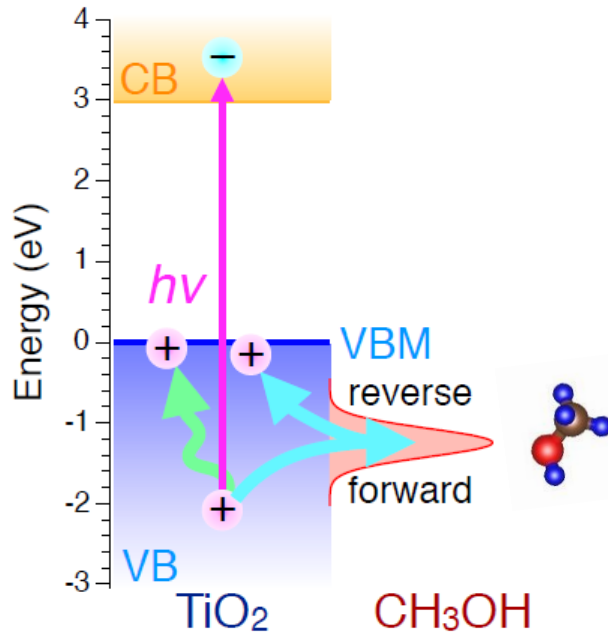
Carrier trapping by molecules

- ✓ **Photochemical reaction on the surface**

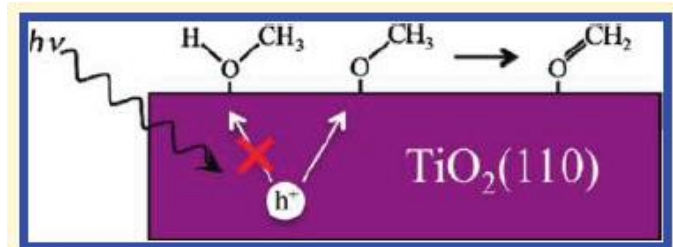
Excited state reaction barrier

Excited Carrier Dynamics

CH₃OH behaves as a hole scavenger on TiO₂



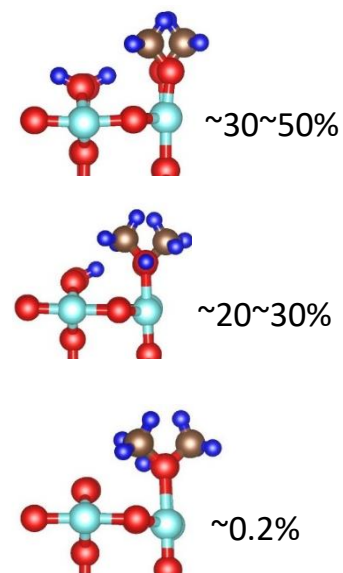
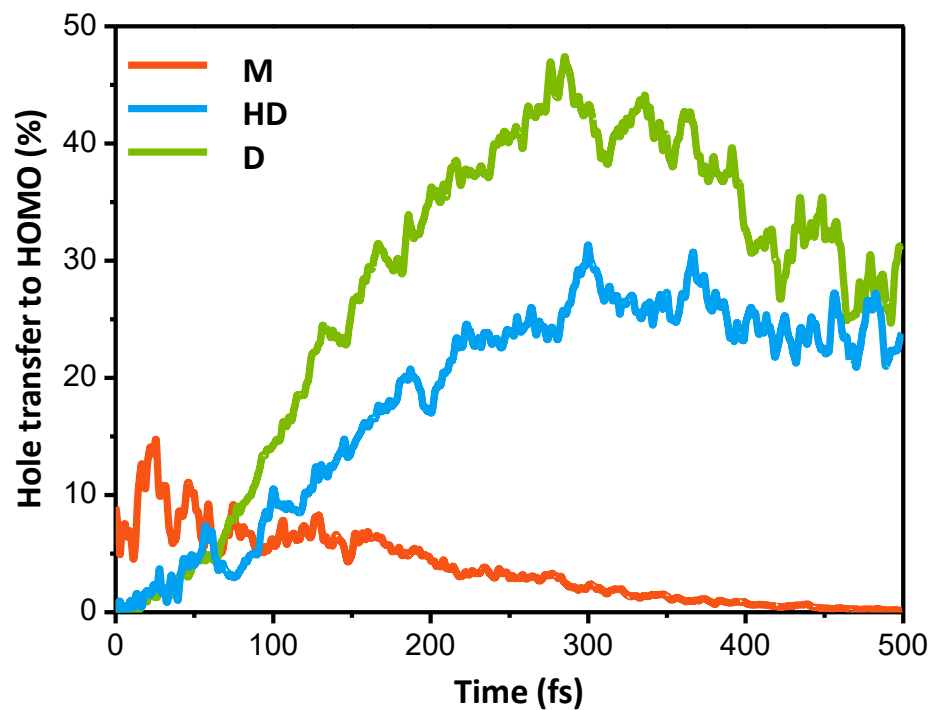
Hole induced dissociation of CH₃OH on TiO₂ observed by Bing Wang et.al.



Henderson et.al. believes that CH₃O is the hole trapper in stead of CH₃OH

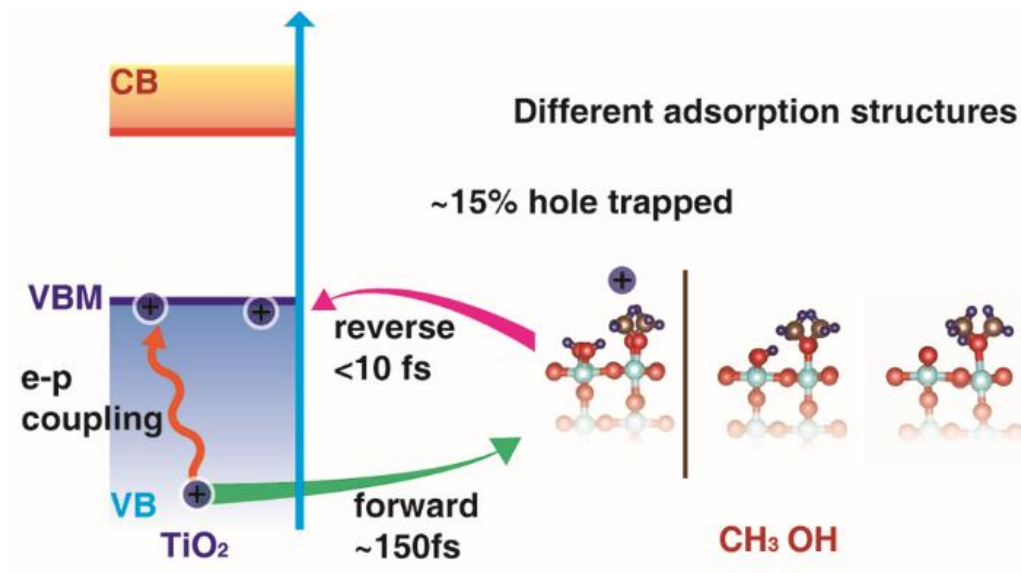
M. Shen and M. A. Henderson, *J. Phys. Chem. Lett.* **2**, 2707-2710 (2011)

Hole trapping sites



Average from 10^5 trajectories

CH₃OH as a Hole Scavenger on TiO₂ Surface

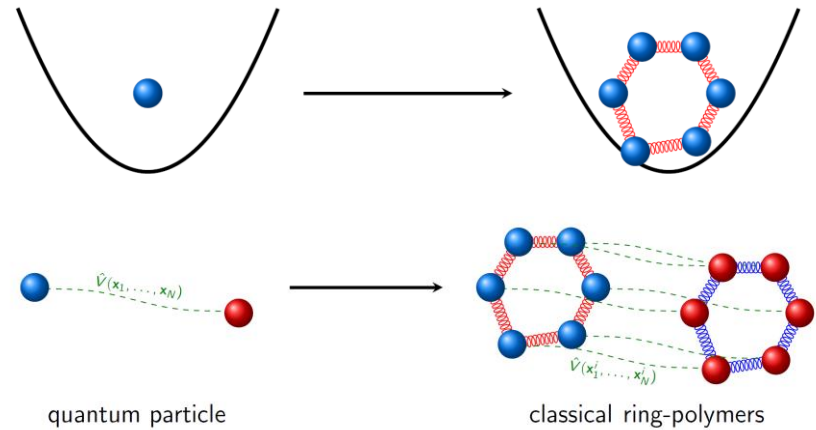
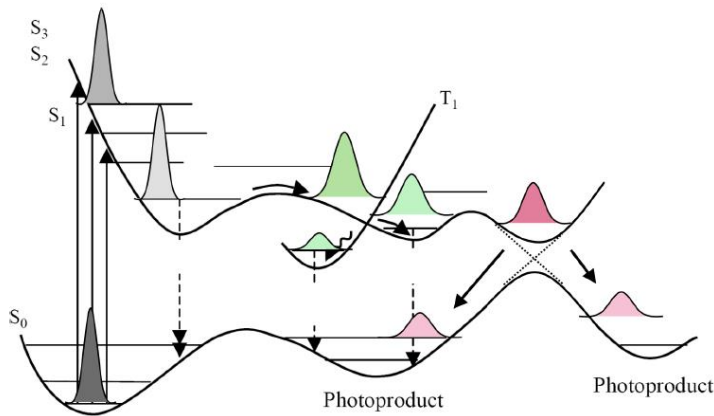


W. Chu, W. A. Saidi, Q. Zheng*, Y. Xie, Z. Lan, O. V. Prezhdo, H. Petek and **J. Zhao*** *J. Am. Chem. Soc.*, 138, 13740, (2016)

Nuclear Quantum Effects in NAMD

Mixed Quantum-Classical

approximation $\hat{H}_{el}(\mathbf{r}; \mathbf{R})\Phi_j(\mathbf{r}; \mathbf{R}) = E_j(\mathbf{R})\Phi_j(\mathbf{r}; \mathbf{R})$

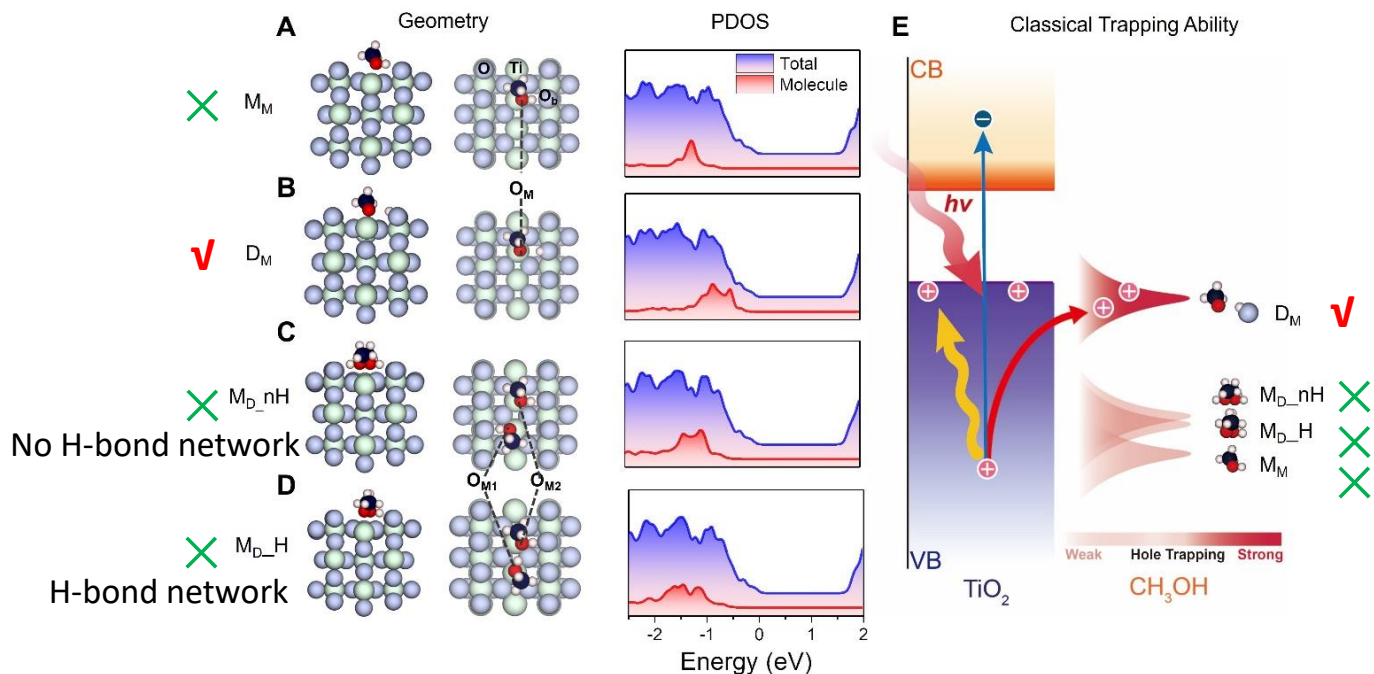


Ring-polymer molecular dynamics (RPMD)

Q: 如何在mixed quantum-classical approximation中考虑核量子效应

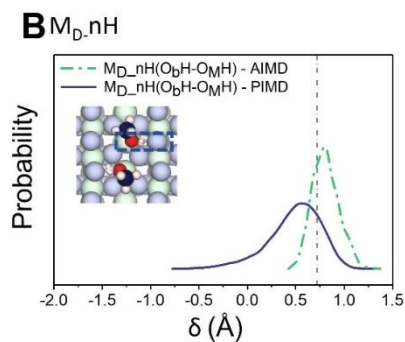
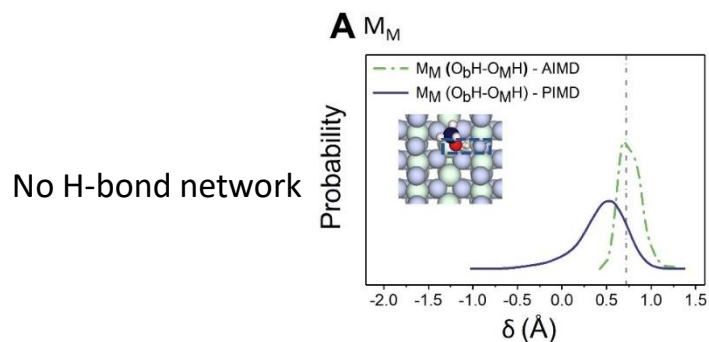
A: RPMD + NAMD

Different Adsorption Structures of CH₃OH on TiO₂

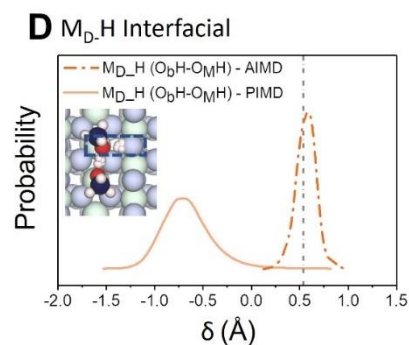
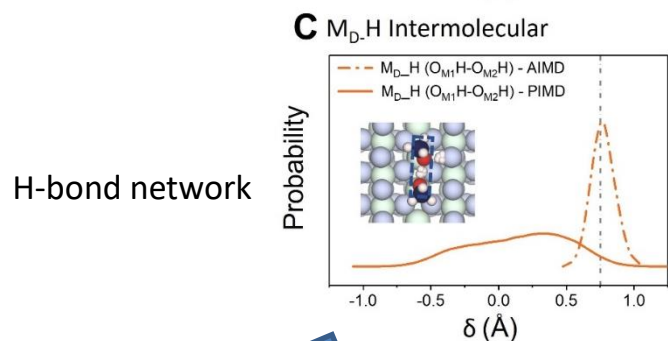


Dissociated CH₃O (D_M) behaves as hole scavenger

Nuclear Quantum effects (NQE) on the Adsorption Structures



$$\delta = R_{O_aH} - R_{O_dH}$$



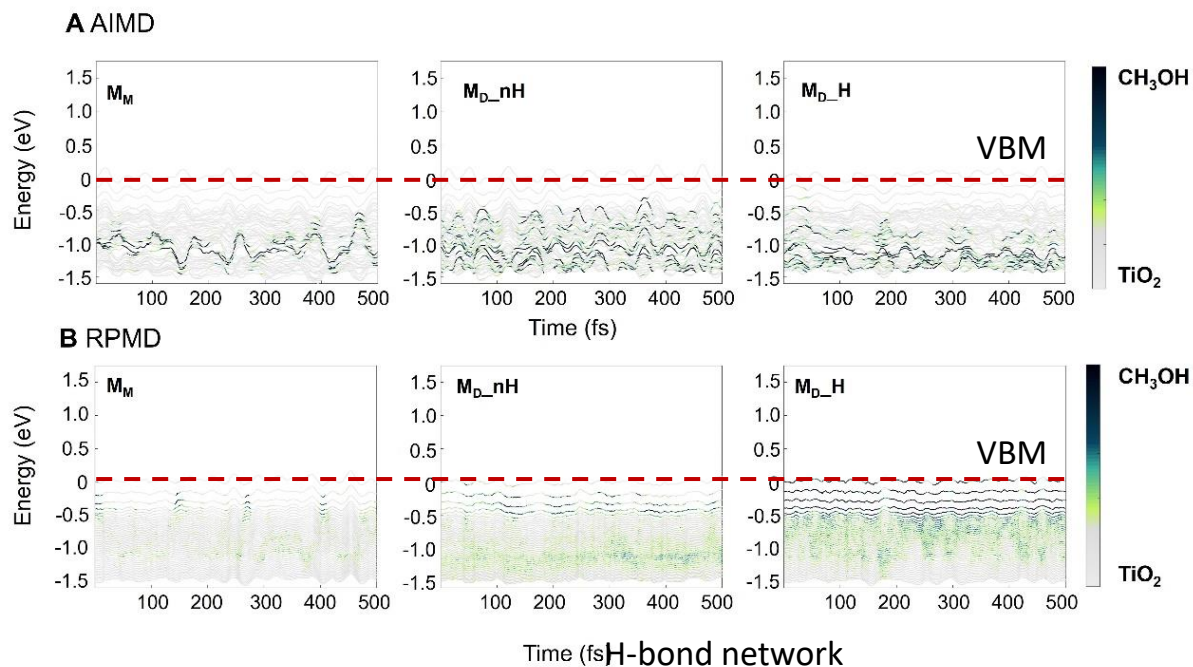
$\delta > 0$ no proton transfer

$\delta < 0$ proton transfer

Quantum proton delocalization

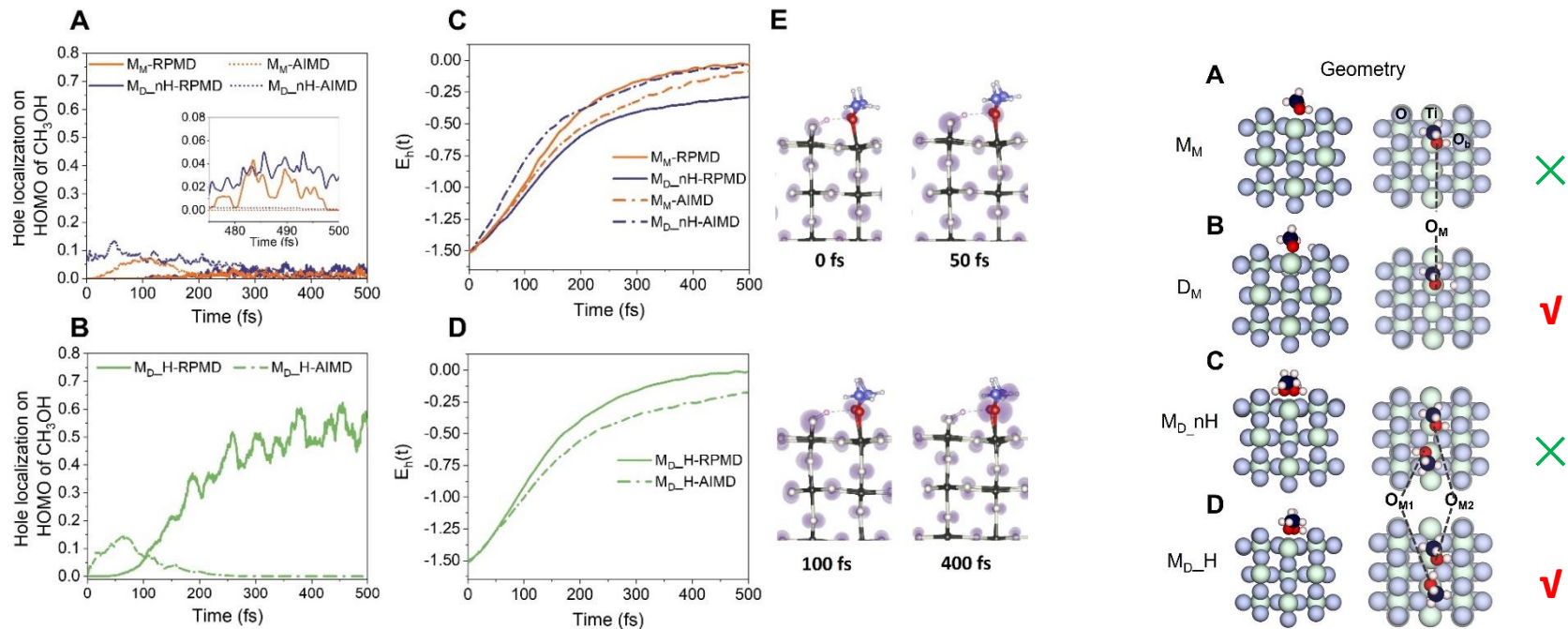
NQEs induced proton transfer

Nuclear Quantum effects on the Energy Level Alignment



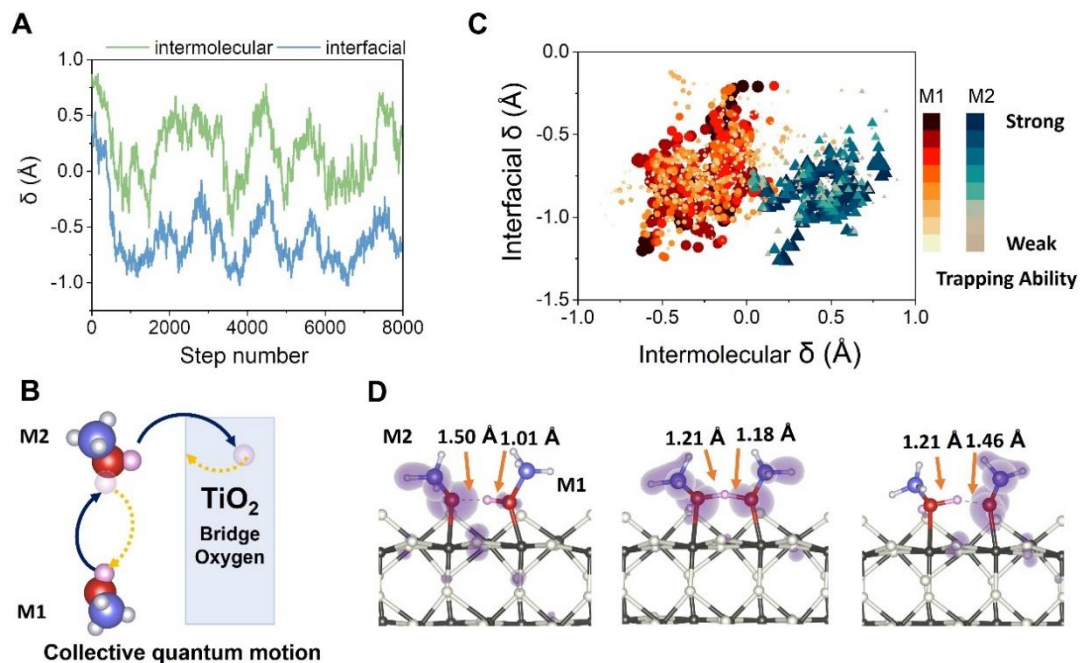
NQEs change the band alignment of M_{D_H} system, where a H-bond network is formed.

Nuclear Quantum Effects on Hole Trapping



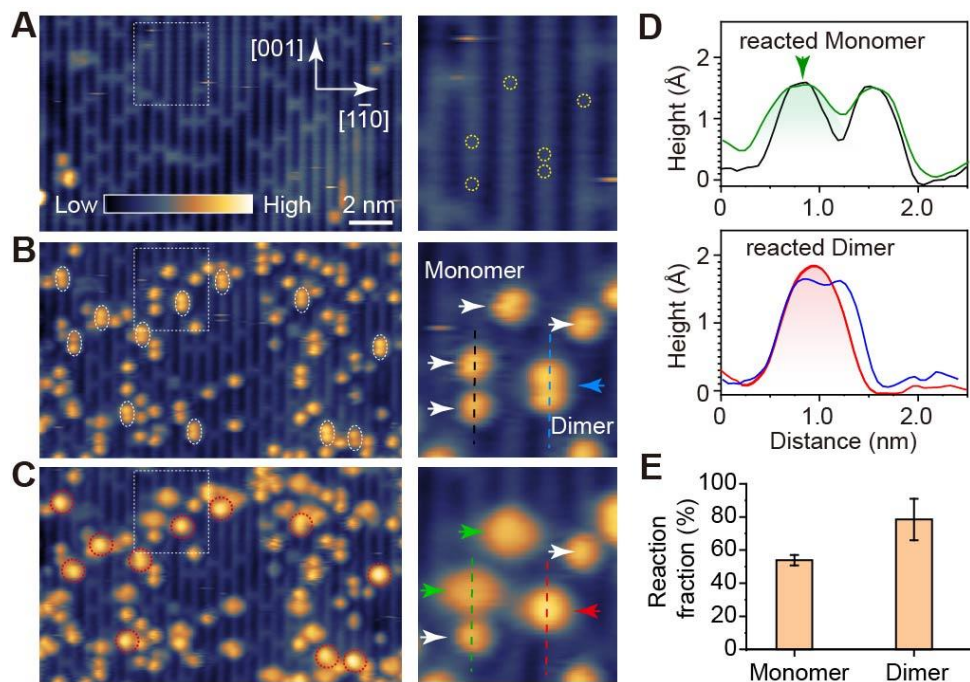
NQEs makes M_{D_H} behave as a hole scavenger.

Collective Nuclear Quantum Motion Coupled Hole Transfer



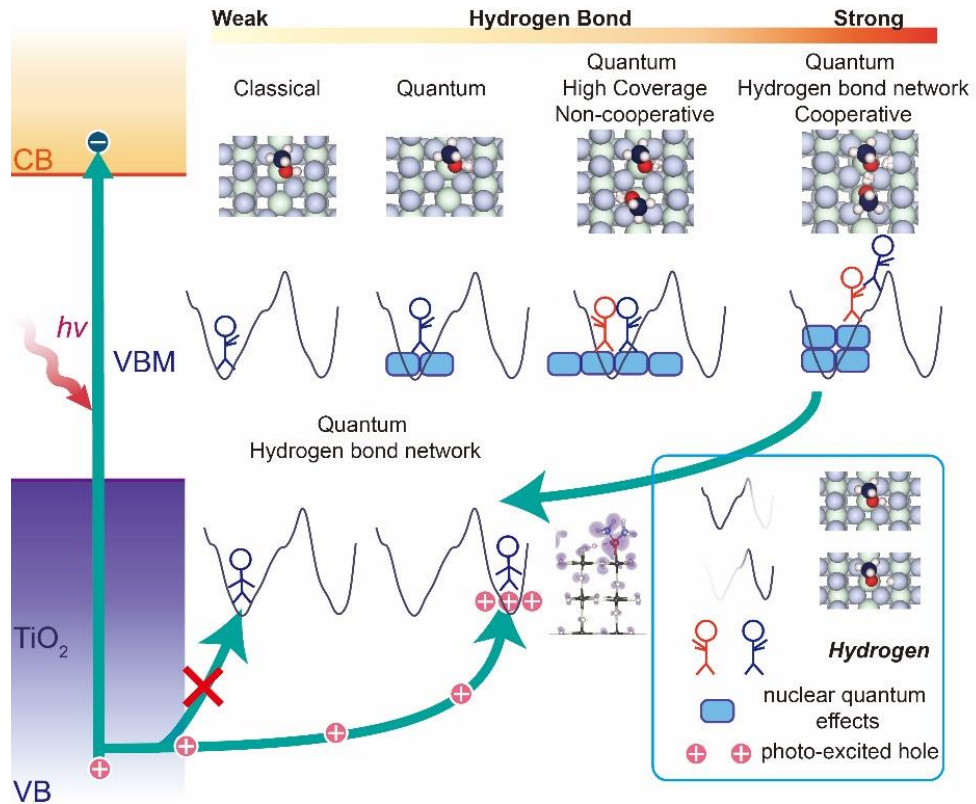
In the H-bond network, the quantum proton motion is collective, which couples with hole trapping dynamics.

Experimental Evidence by STM



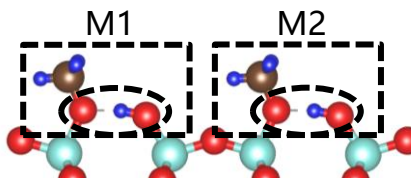
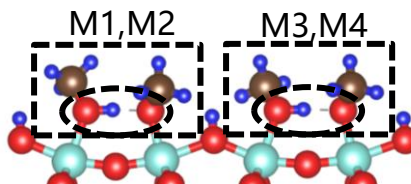
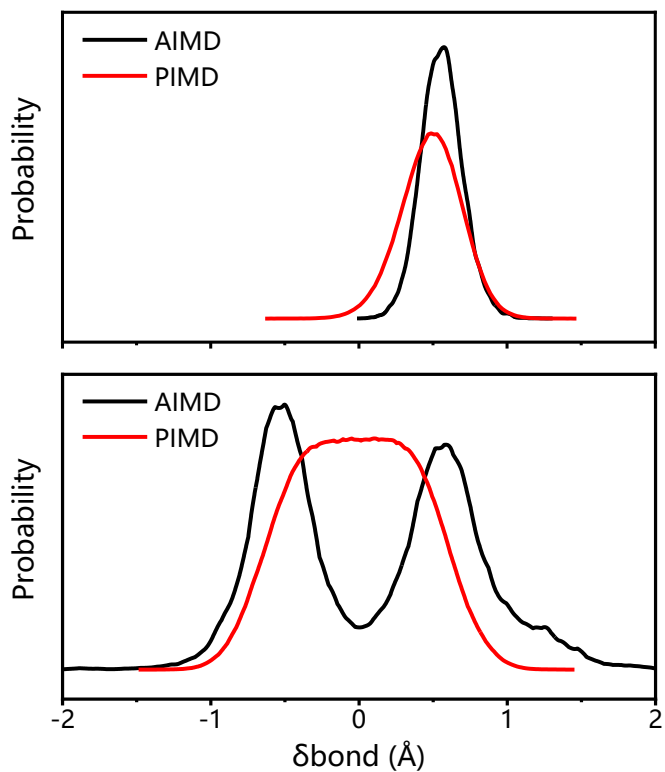
Dimer formation (H-bond network) improves the photochemical reaction rate.

Summary - Example I



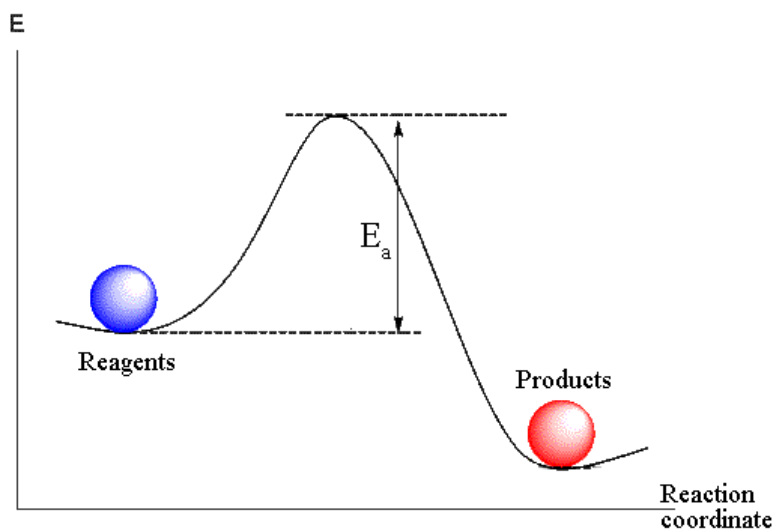
W. Chu *et al.* X. Li*, J. Zhao* *Sci. Adv.* **8**, eabo2675 (2022)

Outlook - Example I



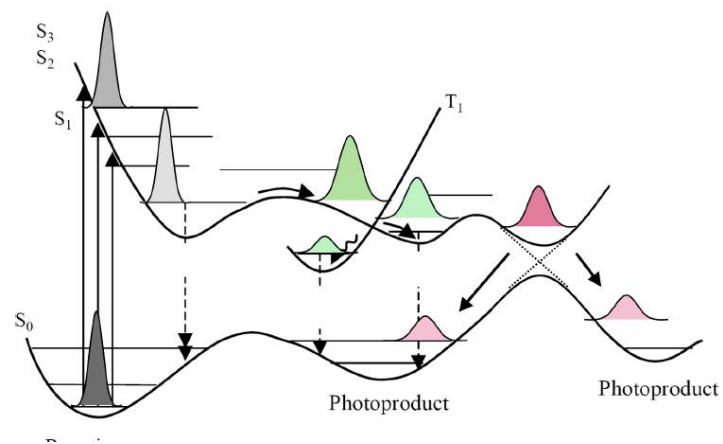
RPMD/PIMD is very expensive!
Machine Learning + PIMD/RPMD

Outlook - Part II



基态催化:

计算反应势垒, 方法非常成熟



光催化:

- ✓ 激发态势能面
- ✓ 势能面交叉
- ✓ 激发态载流子寿命

Back ground

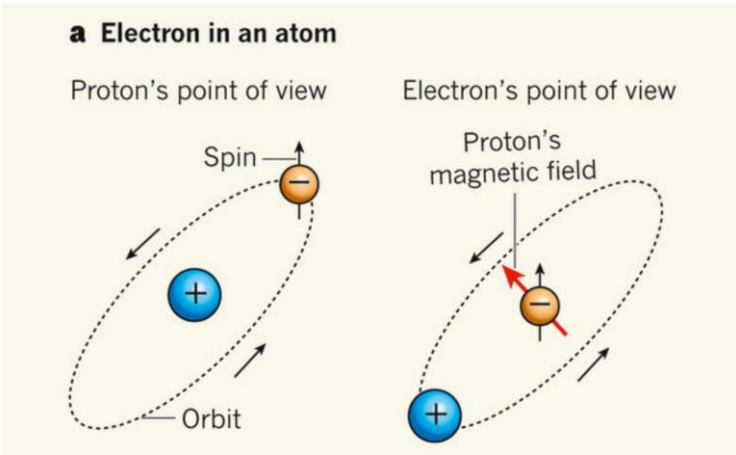
Single particle dynamics

Spin dynamics

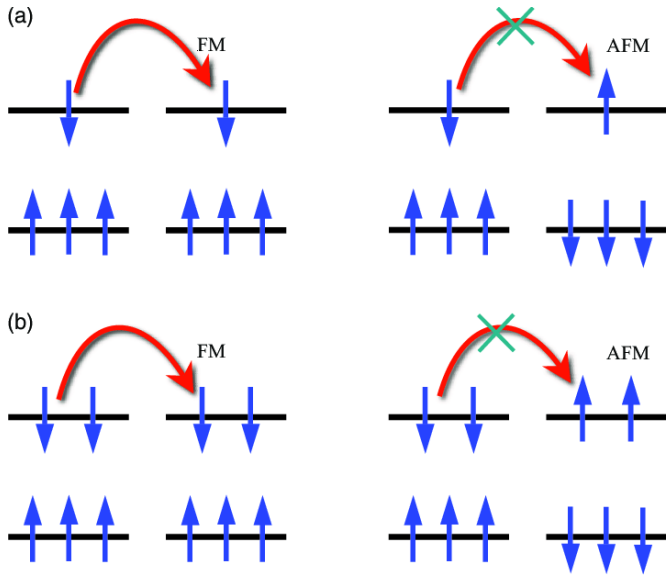
Exciton Dynamics

Outlook

Spin Dynamics

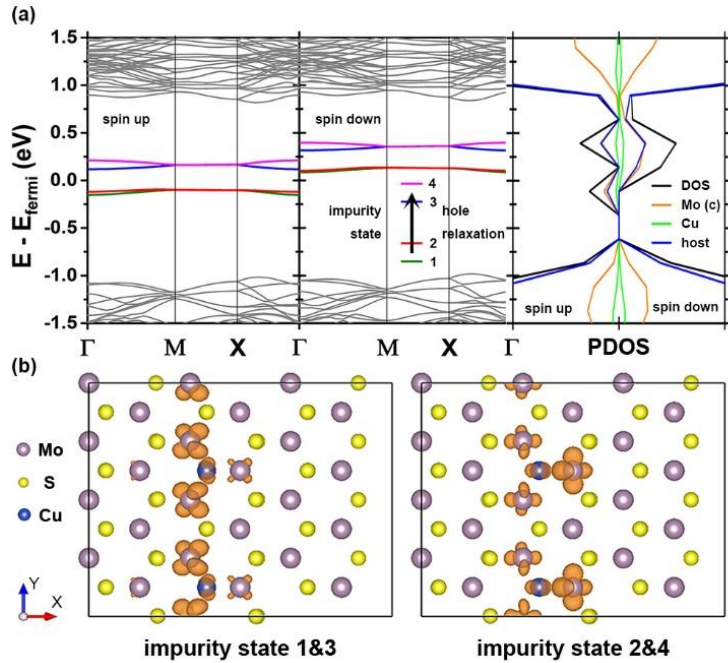


Spin-Orbital Interaction

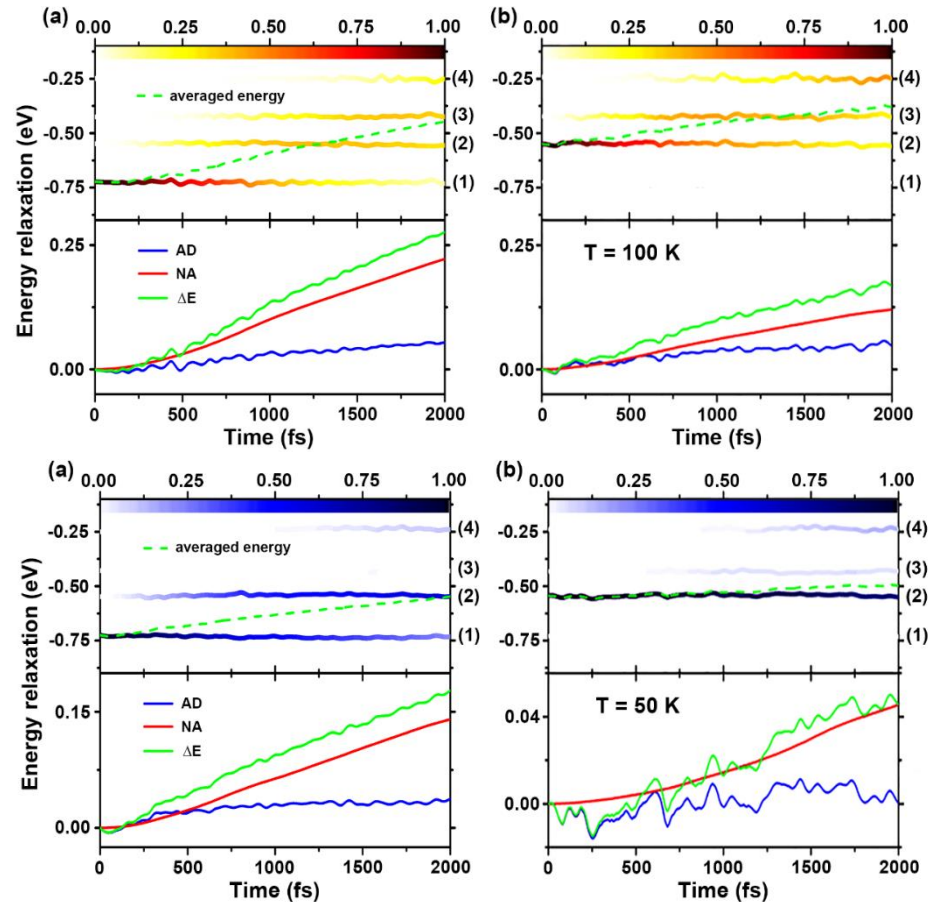


Spin-Spin Interaction

Dynamics of Photogenerated Spin Hole Current



赵传禹



C. Zhao, et al. and J. Zhao*, *Phys. Rev. B* **96**, 134308 (2017)

NAMD with SOC

The time-dependent Schrödinger equation

$$i\hbar \frac{\partial |\Psi(\mathbf{r}, \mathbf{R}(t), \mathbf{s}, t)\rangle}{\partial t} = \hat{\mathcal{H}}^{tot}(\mathbf{r}, \mathbf{R}(t), \mathbf{s}) |\Psi(\mathbf{r}, \mathbf{R}(t), \mathbf{s}, t)\rangle \quad (1)$$

where the total Hamiltonian is given by

$$\hat{\mathcal{H}}^{tot}(\mathbf{r}, \mathbf{R}(t), \mathbf{s}) = \hat{\mathcal{H}}^0(\mathbf{r}, \mathbf{R}(t)) + \hat{\mathcal{H}}^{soc}(\mathbf{r}, \mathbf{R}(t), \mathbf{s}) \quad (2)$$

by expanding the wavefunction with a basis set $\{|\psi_i\rangle\}$ or different representations

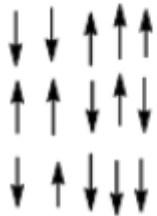
$$|\Psi\rangle = \sum_i |\psi_i\rangle \langle \psi_i | \Psi \rangle = \sum_i c_i |\psi_i\rangle \quad (3)$$

and substituting eq (3) into eq (1), we have

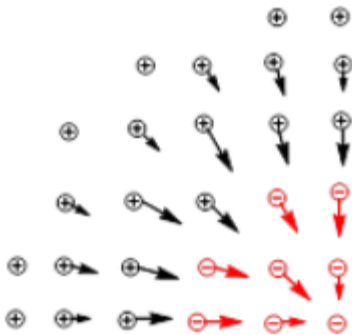
$$\begin{aligned} \frac{\partial c_j(t)}{\partial t} &= - \sum_i \left[i\hbar^{-1} \langle \psi_j | \hat{\mathcal{H}}^{tot} | \psi_i \rangle + \langle \psi_j | \frac{d}{dt} | \psi_i \rangle \right] c_i(t) \\ &= - \sum_i \left[i\hbar^{-1} \langle \psi_j | \hat{\mathcal{H}}^0 | \psi_i \rangle + i\hbar^{-1} \langle \psi_j | \hat{\mathcal{H}}^{soc} | \psi_i \rangle + \langle \psi_j | \frac{d}{dt} | \psi_i \rangle \right] c_i(t) \\ &= - \sum_i \left(i\hbar^{-1} H_{ji}^0 + i\hbar^{-1} H_{ji}^{soc} + T_{ji} \right) c_i(t) \end{aligned} \quad (4)$$

Choices of Representations

Ising Model –
vectors point
UP OR DOWN
ONLY → simplest



Heisenberg Model –
vectors point in
any direction
IN SPACE



- “Spin-diabatic” representation
 - $H_{ji}^0 = E_j \delta_{ji}$, i.e. $\{|\psi_i\rangle\} \Rightarrow$ eigenstates of $\hat{\mathcal{H}}^0$.
 - $H_{ji}^{SOC} = 0$ for same spin multiplicity.
 - $T_{ji} = 0$ for different spin multiplicity.
 - Used with *weak* SOC.
- “Spin-adiabatic” representation
 - $H_{ji}^0 + H_{ji}^{SOC} = \Lambda_{ji} \delta_{ji}$, i.e. $\{|\psi_i\rangle\} \Rightarrow$ eigenstates of $\hat{\mathcal{H}}^{tot}$.
 - Hopping solely determined by T_{ji} .
 - *Strong* SOC.

The hopping probability within FSSH

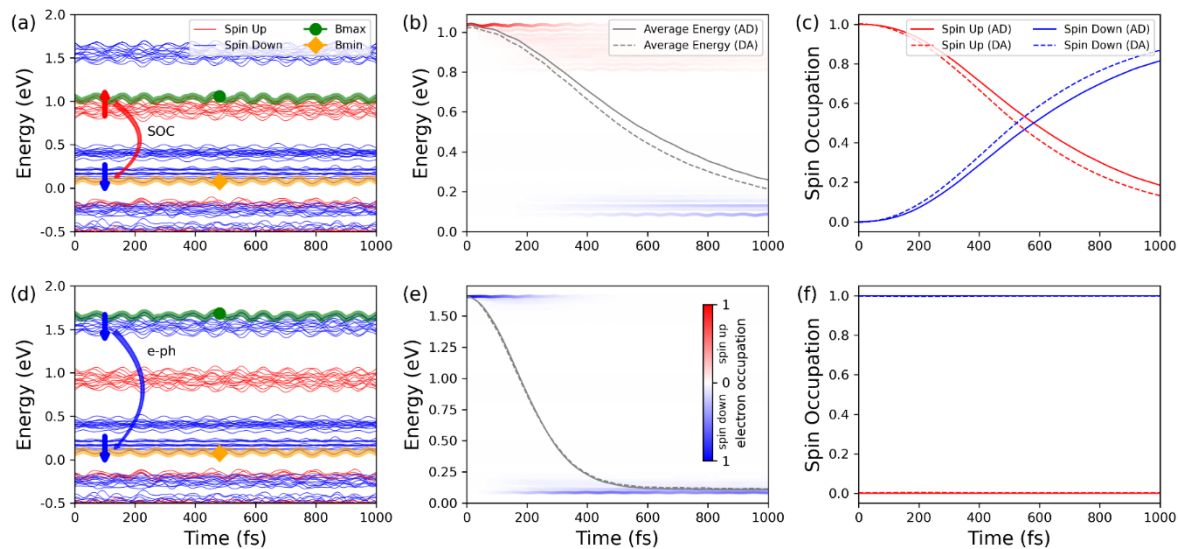
$$P_{j \rightarrow k}(t, \Delta t) = \max \left(- \frac{2\Delta t \left[\hbar^{-1} \text{Im}(c_j^* c_k (H_{jk}^0 + H_{jk}^{SOC})) - \text{Re}(c_j^* c_k T_{jk}) \right]}{c_j^* c_j}, 0 \right)$$



郑奇靖

Ni金属自旋轨道耦合引发超快退磁过程

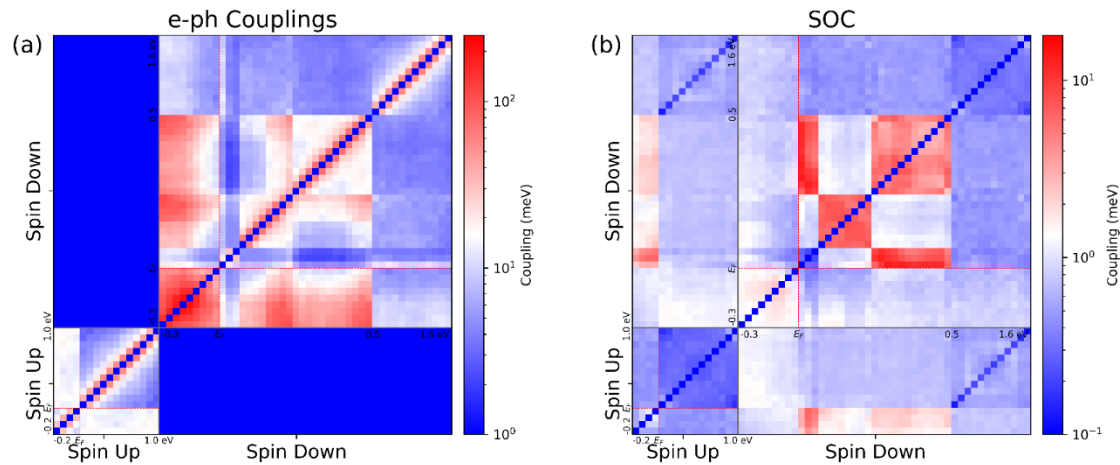
Spin up electrons **will** flip to Spin down electrons due to SOC



Spin down electrons **will NOT** flip to Spin up electrons due to SOC
They will decay to spin down electrons with lower energies.

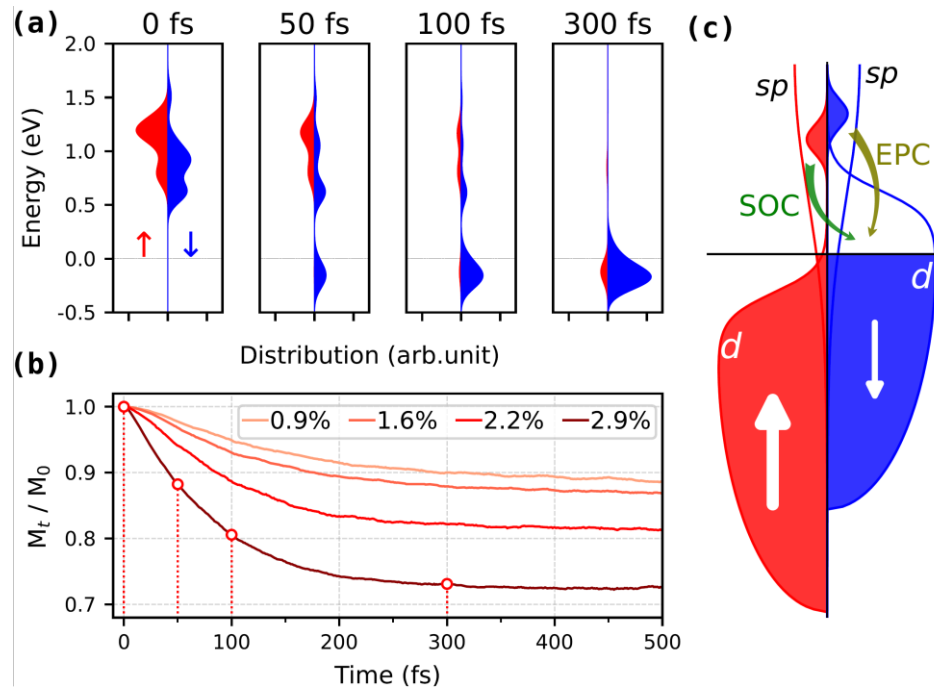
自旋轨道耦合与电声耦合

$$H_{ki} = \epsilon_k \delta_{ik} - i\hbar \left\langle k \left| \frac{\partial}{\partial t} \right| i \right\rangle + i\hbar \langle k | \mathcal{H}^{SOC} | i \rangle$$



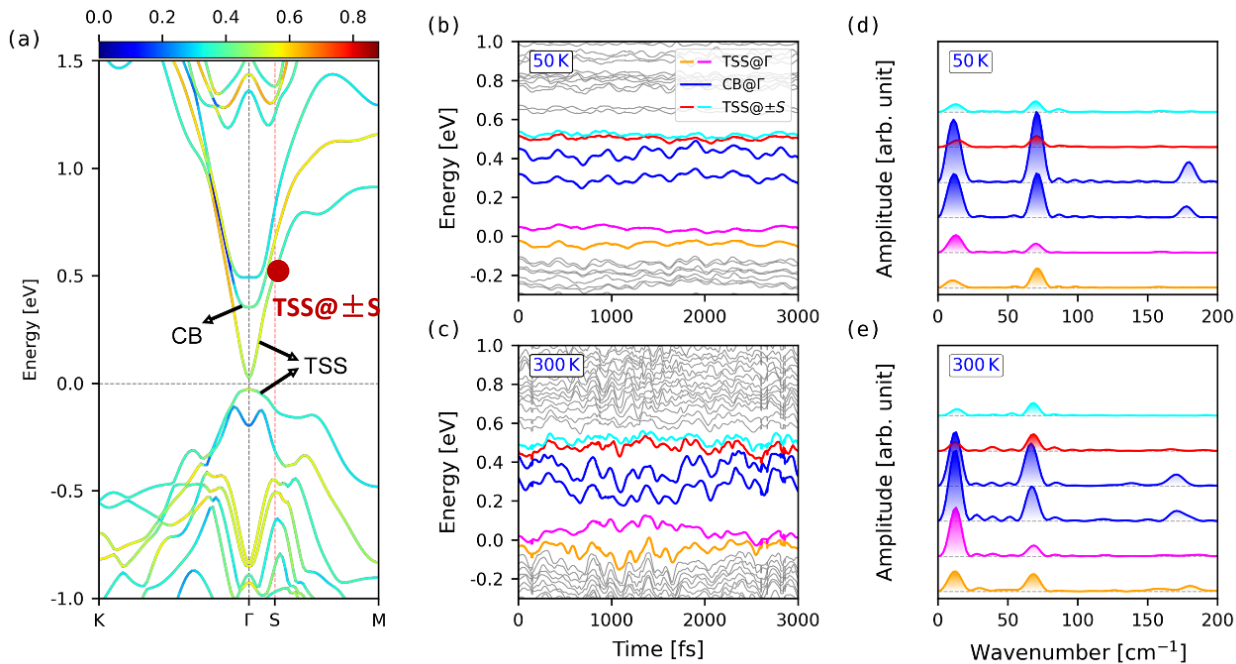
In Ni, e-ph coupling > SOC. The electron tends to decay through the orbitals with the same spin.

Ni体系超快退磁



Z. Zheng, Q. Zheng*, J. Zhao*, *Phys. Rev. B* **105**, 085142 (2022)

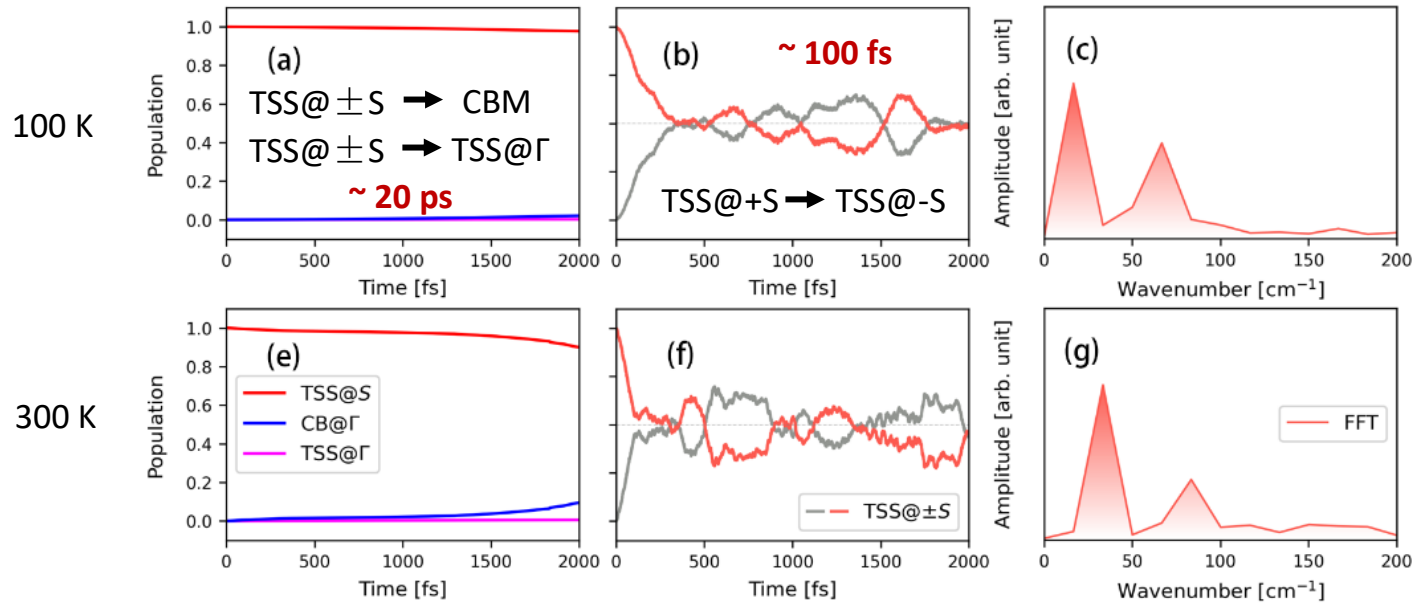
Excited Electron Dynamics in Bi_2Se_3



Back scattering between $\text{TSS}@+S$ and $\text{TSS}@-S$ is **forbidden**

$$|+\rangle = \mathcal{T}|-\rangle \quad \langle +|U|-\rangle = 0$$

Backscattering Between two TSS@±S Time-Reversal Partners



$$d_{jk} = -i\hbar \left\langle \varphi_j \left| \frac{\partial}{\partial t} \right| \varphi_k \right\rangle = -i\hbar \frac{\langle \varphi_j(t) | \varphi_k(t + \Delta t) \rangle - \langle \varphi_j(t + \Delta t) | \varphi_k(t) \rangle}{2\Delta t}$$

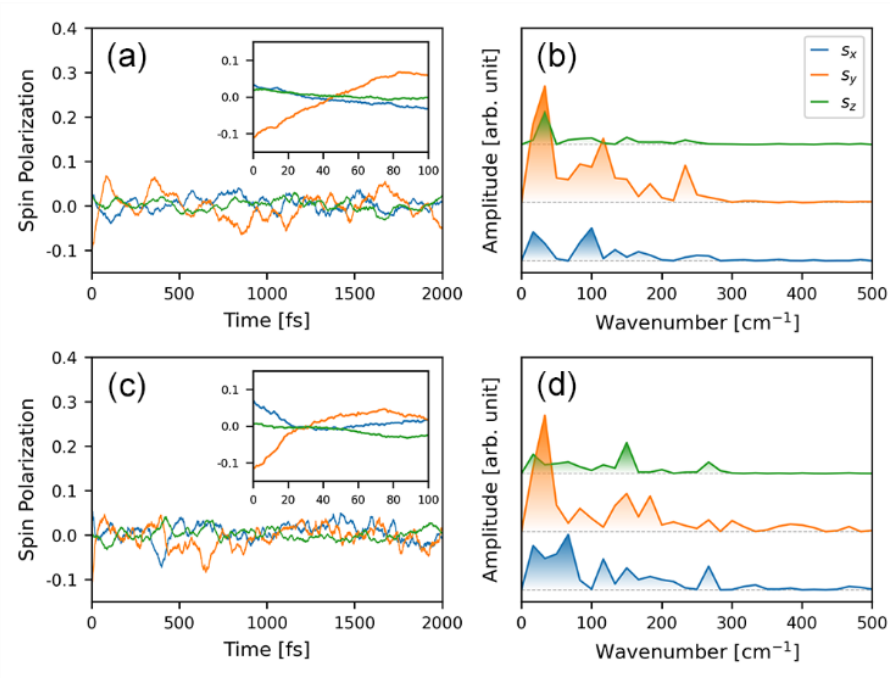
$$|+\rangle = \mathcal{T}|-\rangle \quad \langle +|U|-\rangle = 0$$

Without phonon excitation

$$|+, (t + \Delta t)\rangle \neq \mathcal{T}|-, t\rangle \quad \langle +, t|-, (t + \Delta t)\rangle \neq 0$$

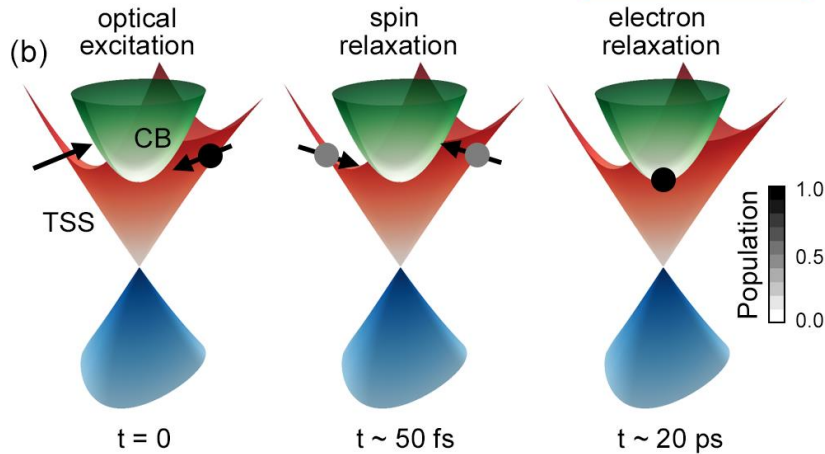
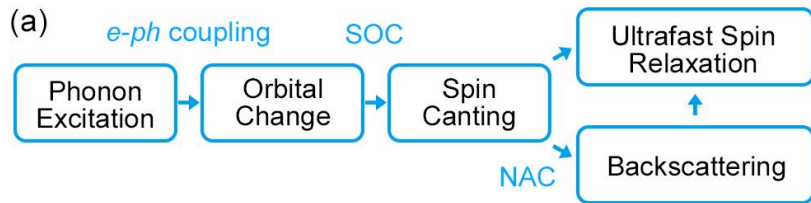
With phonon excitation

Excited State Spin Dynamics in Bi_2Se_3

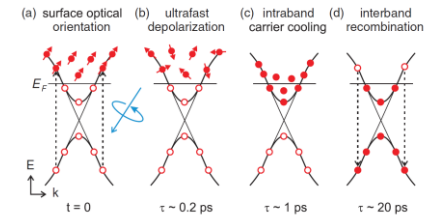


Spin canting occurs in ~ 50 fs

Ultrafast Spin Relaxation of the Excited TSS Electron



C. Zhao, Q. Zheng*, J. Zhao*, *Fundamental Research* in press



N. Gedik* et al. *Phys. Rev. Lett.* 107, 077401 (2011)

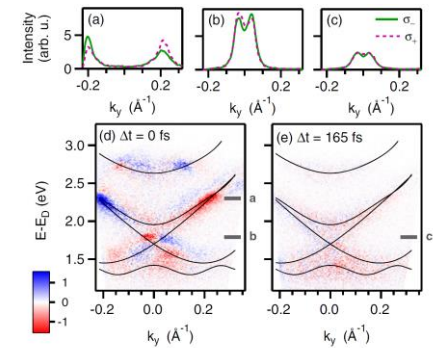


FIG. 2. Helicity-dependent population asymmetry. (a)–(c) Momentum distribution curves (MDCs) of the unoccupied band structure, excited with σ_+ (dashed purple line) and σ_- (solid green line) polarized pulses. (a) and (b) were taken at $\Delta t = 0$, and (c) at $\Delta t = 165$ fs, at the energies marked by the short gray lines in (d) and (e). (d),(e) Asymmetry image: Difference between the populations of the unoccupied bands when excited by σ_- and σ_+ polarized pulses, taken at $\Delta t = 0$ and 165 fs respectively. Black lines are guides to the eye that follow the dispersions of the unoccupied bands.

Z. X. Shen* et al. *Phys. Rev. Lett.* 122, 167401 (2019)

Back ground

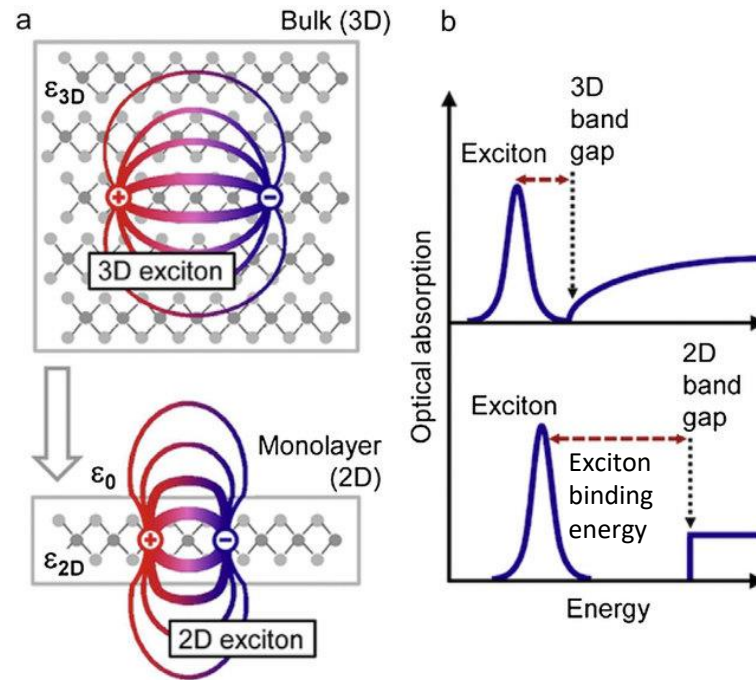
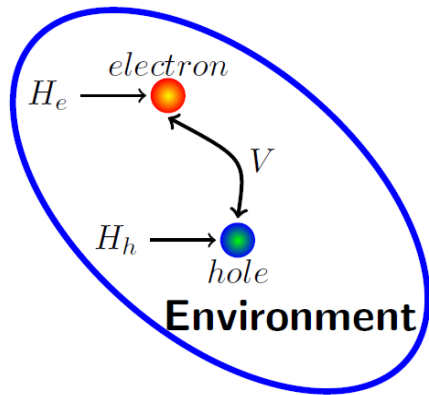
Single particle dynamics

Spin dynamics

Exciton Dynamics

Outlook

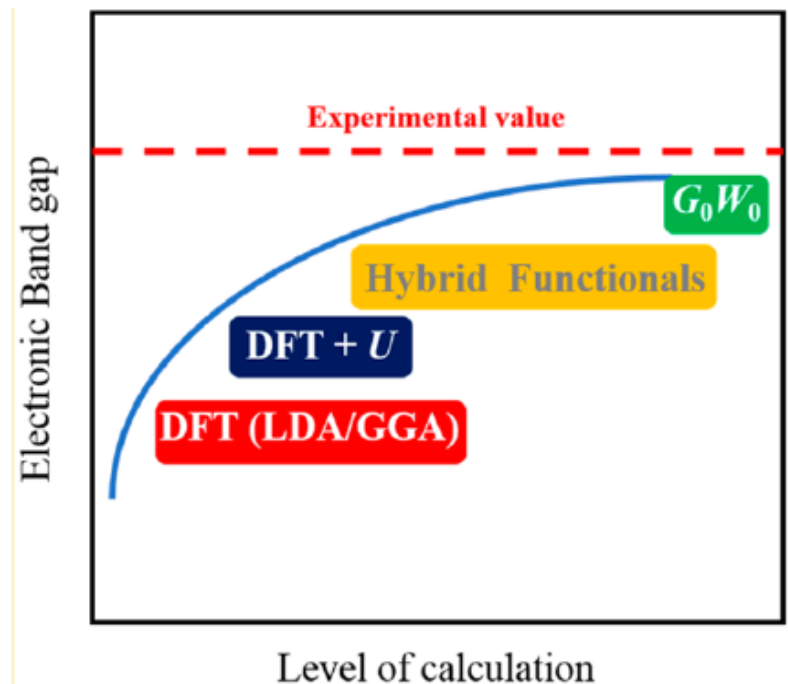
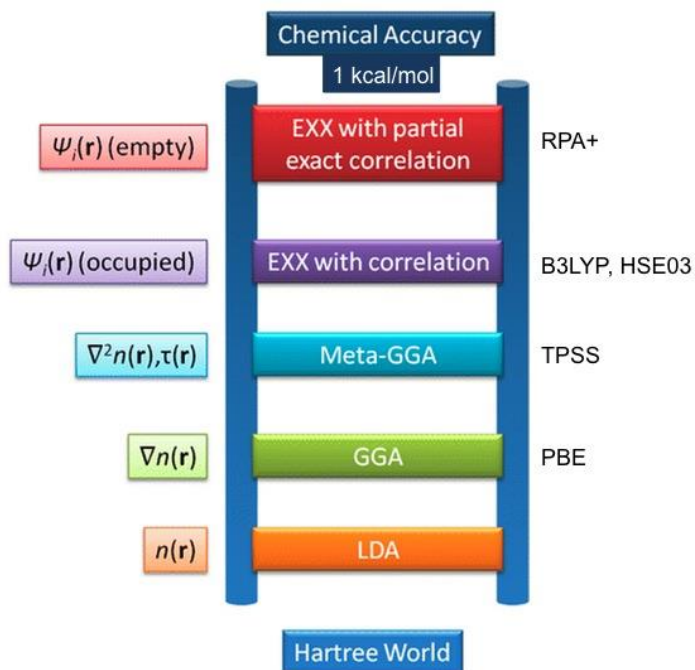
Excitons in 2D Materials



A. Chernikov et al. *Phys. Rev. Lett.* **113** 076802 (2014)

2D materials: quantum confinement significantly reduce the dielectric screening and increase the exciton binding energy

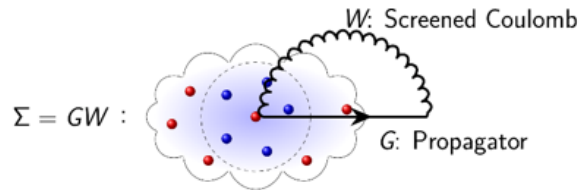
Failure of DFT



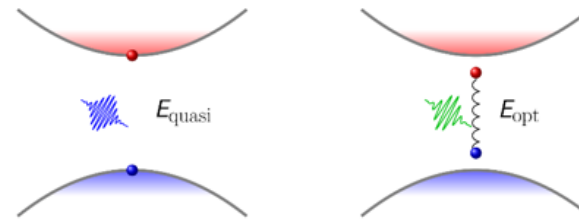
<https://www.sas.upenn.edu/~jianmint/Research/>

A. Morales-Garcia et al. J. Phys. Chem. C, 121, 18862 (2017)

GW + BSE to Describe the Exciton



$$\Sigma^{\text{GW}}(\mathbf{r}, \mathbf{r}', \omega) = -\frac{i}{2\pi} \int d\omega' e^{i\omega\eta} G(\mathbf{r}, \mathbf{r}', \omega + \omega') W(\mathbf{r}, \mathbf{r}', \omega')$$



$$H_{c'v'k'}^{cvk} = [E_{ck}^{\text{QP}} - E_{vk}^{\text{QP}}] \delta_{cc'} \delta_{v'v} \delta_{kk'} - W_{c'v'k'}^{cvk} + 2v_{c'v'k'}^{cvk}$$

GW: self-energy take place of exchange correlation potential

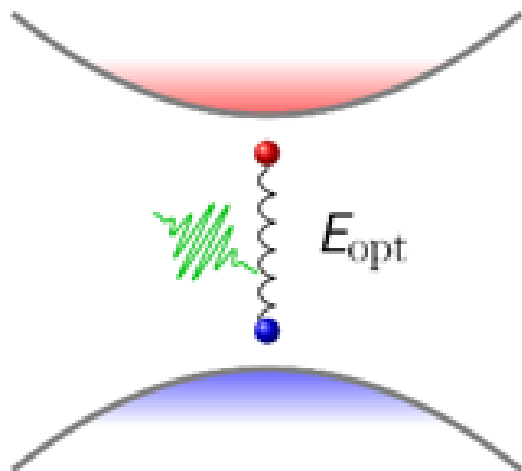
Accurate Quasi-particle energies



Bethe-Salpeter Equation (BSE): Screened Coulomb (W) and exchange (v) interaction of electron and hole

Exciton binding energy and wave function

Exciton Dynamics is Important



Exciton dynamics:

Exciton relaxation

Bright-to-dark transition

Single-to-multi transition

Singlet fission

Exciton annihilation (radiative and nonradiative)

...

10,000 times of GW+BSE calculations are too expensive!

Realization of *GW* + Real-Time BSE

BSE Hamiltonian: $\langle \mathbf{k}c\nu | H | \mathbf{k}'c'\nu' \rangle = \left(E_{\mathbf{k}c}^{QP} - E_{\mathbf{k}\nu}^{QP} \right) \delta_{\mathbf{k}\mathbf{k}'} \delta_{cc'} \delta_{\nu\nu'} - W_{\mathbf{k}'c'\nu'}^{\mathbf{k}c\nu} + V_{\mathbf{k}'c'\nu'}^{\mathbf{k}c\nu}$

From *GW*

Coulomb Interaction: $W_{\mathbf{k}'c'\nu'}^{\mathbf{k}c\nu} = \frac{1}{\Omega} \sum_{\mathbf{G}\mathbf{G}'} \frac{4\pi \epsilon_{\mathbf{G}\mathbf{G}'}^{-1}(\mathbf{k}-\mathbf{k}')}{|\mathbf{k}-\mathbf{k}'+\mathbf{G}| |\mathbf{k}-\mathbf{k}'+\mathbf{G}'|} \left(B_{\uparrow\mathbf{k}'c'}^{\uparrow\mathbf{k}c}(\mathbf{G}) + B_{\downarrow\mathbf{k}'c'}^{\downarrow\mathbf{k}c}(\mathbf{G}) \right) \left(B_{\uparrow\mathbf{k}'\nu'}^{\uparrow\mathbf{k}\nu^*}(\mathbf{G}') + B_{\downarrow\mathbf{k}'\nu'}^{\downarrow\mathbf{k}\nu^*}(\mathbf{G}') \right)$

Exchange Interaction: $V_{\mathbf{k}'c'\nu'}^{\mathbf{k}c\nu} = \frac{1}{\Omega} \sum_{\mathbf{G} \neq 0} \frac{4\pi}{|\mathbf{G}|^2} \left(B_{\uparrow\mathbf{k}\nu}^{\uparrow\mathbf{k}c}(\mathbf{G}) + B_{\downarrow\mathbf{k}\nu}^{\downarrow\mathbf{k}c}(\mathbf{G}) \right) \left(B_{\uparrow\mathbf{k}'\nu'}^{\uparrow\mathbf{k}'c'^*}(\mathbf{G}) + B_{\downarrow\mathbf{k}'\nu'}^{\downarrow\mathbf{k}'c'^*}(\mathbf{G}) \right)$

from time-dependent Kohn-Sham basis sets

Rigid dielectric function during MD

QP energy: Rigid shift from KS energy

10,000 real-time *GW* + BSE
- 1 *GW* + real-time BSE

Realization of *GW* + Real-Time BSE

Single-particle

$$\text{TDDFT}$$
$$i\hbar \frac{\partial \psi(r, t)}{\partial t} = \mathcal{H}(r; R) \psi(r, t)$$

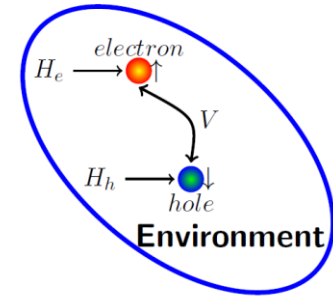


$$\text{Real-time - BSE}$$
$$i\hbar \frac{\partial \psi(r_e, r_h, t)}{\partial t} = \mathcal{H}(r; R) \psi(r_e, r_h, t)$$

two-particle

Hamiltonian:

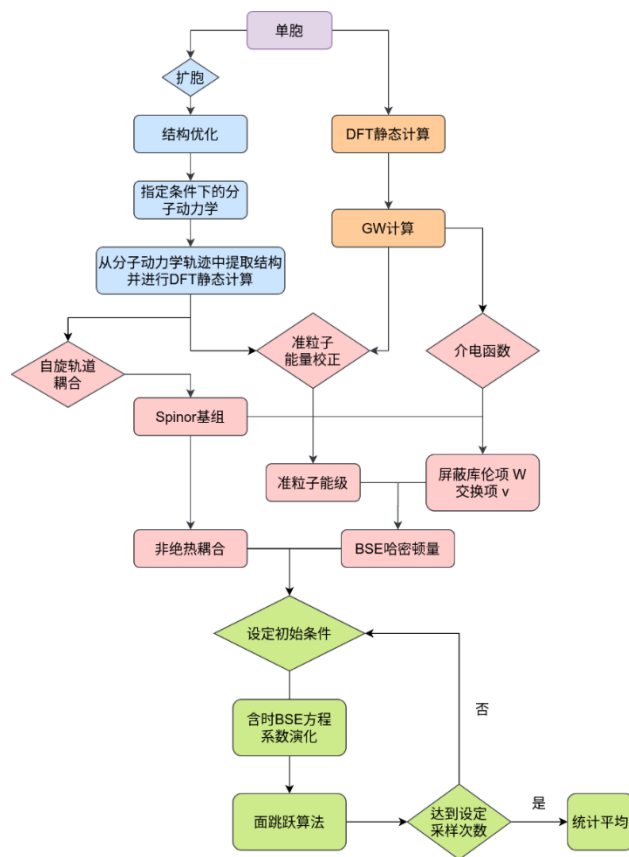
$$H = H_e + H_h + V_{e-h} + H^{SO}$$



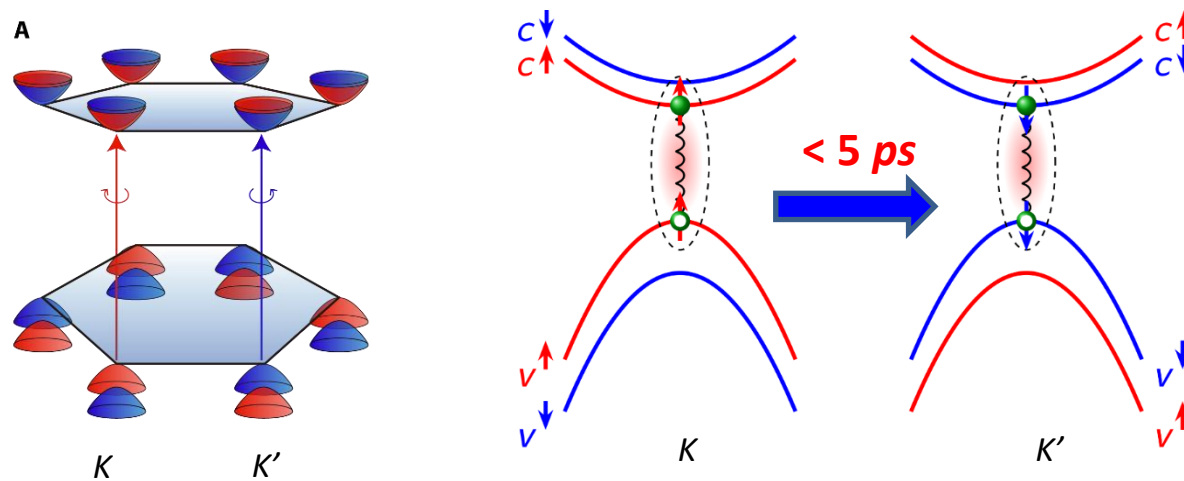
Spin orbital coupling

- ✓ **Many-body interaction:** Coulomb and exchange
- ✓ **Exciton-phonon interaction:** real-time BSE + molecular dynamics
- ✓ **Spin orbital coupling:** adiabatic and diabatic representation
- ✓ **Nonadiabatic:** surface hopping

含时激子动力学方法实现



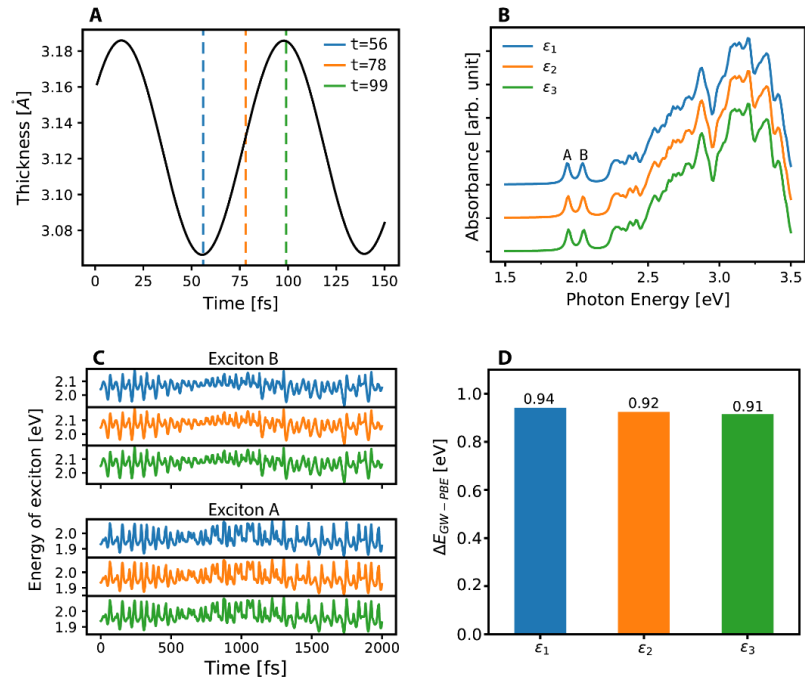
Fast Intervalley Bright Exciton Scattering in Transition Metal Dichalcogenide



Intervalley bright exciton scattering requires the **spin flip** and **momentum transition** of **both electron and hole**

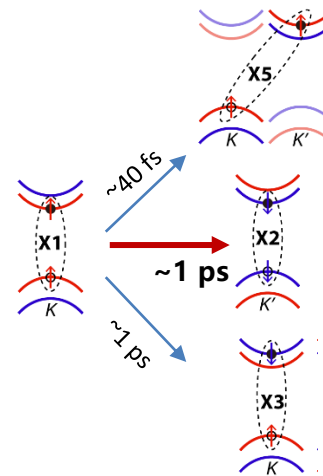
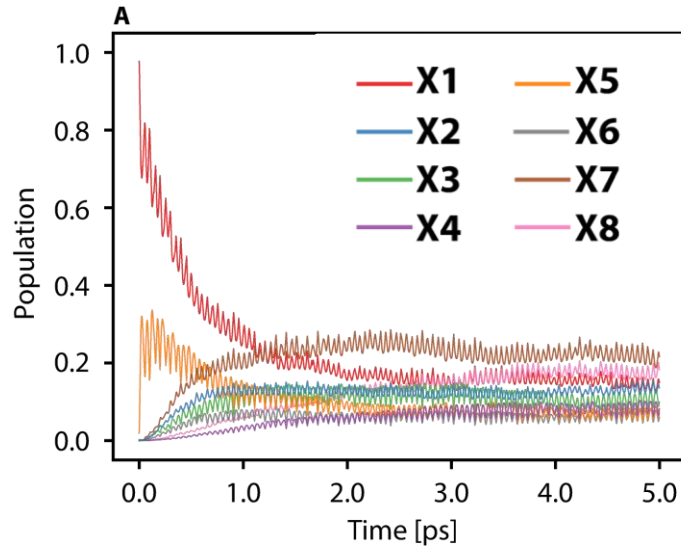
Puzzle: how can such intervalley bright exciton happen within **several picoseconds**?

Test of the Dielectric Function Approximation

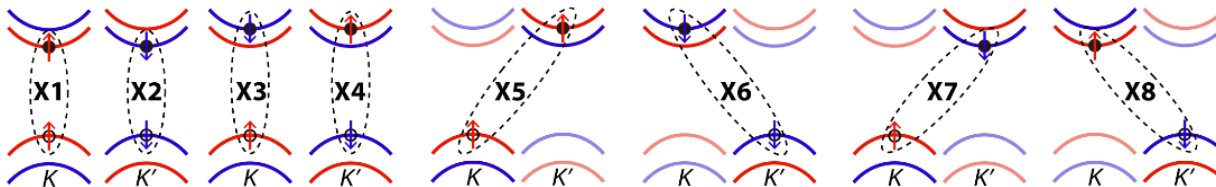


The **dielectric function** and **GWQP correction** almost **does not change** with the structure

Exciton Dynamics in MoS₂



Bright Exciton transition happens in several ps

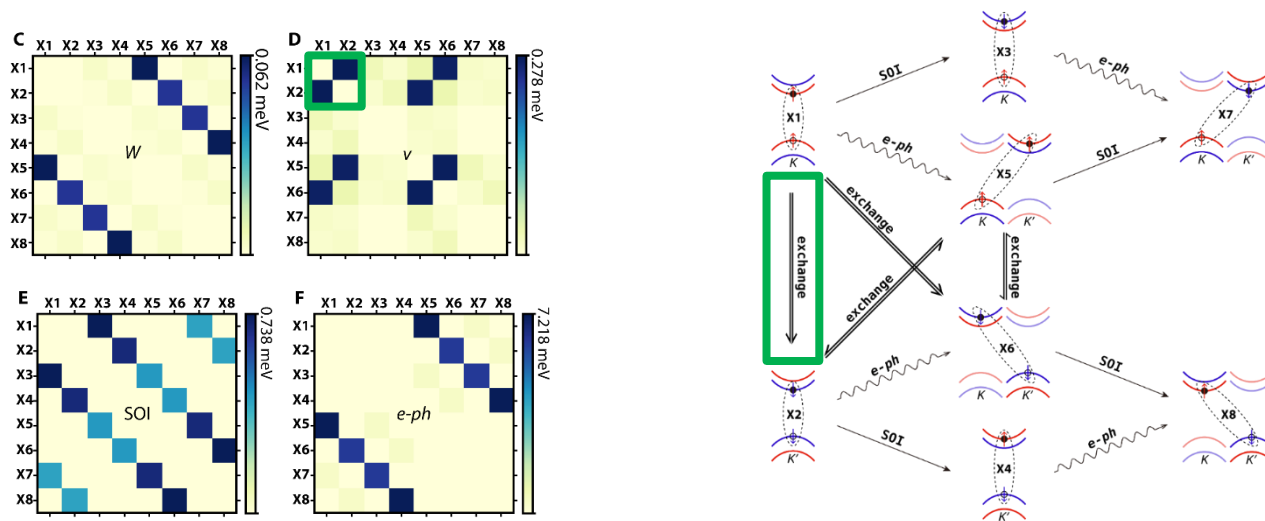


Exchange Interaction Induced Bright Exciton Scattering

Nonadiabatic Coupling Elements:

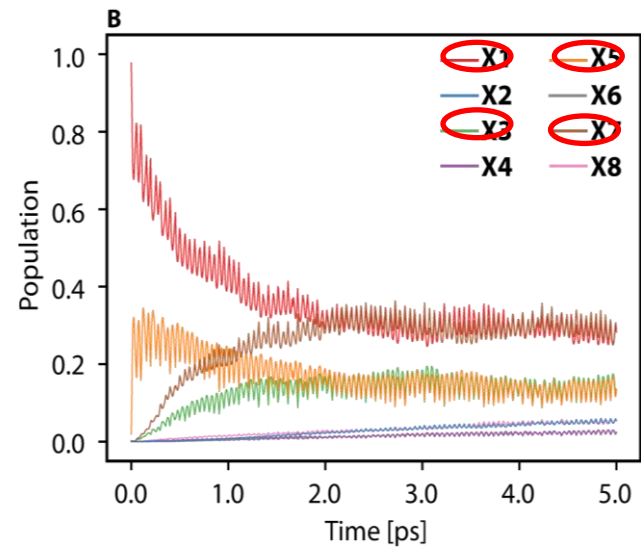
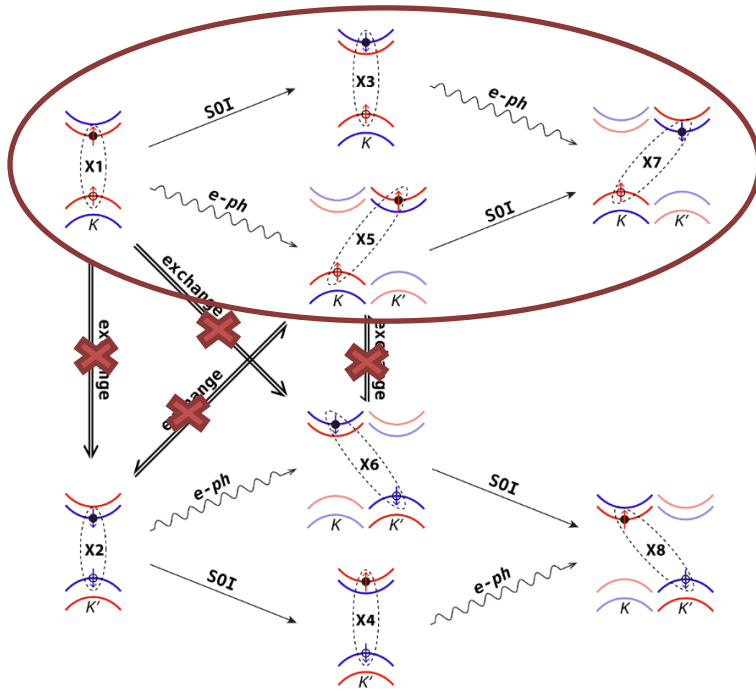
Single particle dynamics: $e-ph$

Exciton dynamics: $e-ph + W(e-h \text{ Coulomb}) + v(e-h \text{ exchange}) + \text{SOC}$



Bright Exciton transition is induced by $e-h$ exchange interaction

Single Particle Picture



Spin particle picture: photoexcited hole keeps in K valley

Summary

Single-particle

$$\text{TDDFT}$$

$$i\hbar \frac{\partial \psi(r, t)}{\partial t} = \mathcal{H}(r; R) \psi(r, t)$$

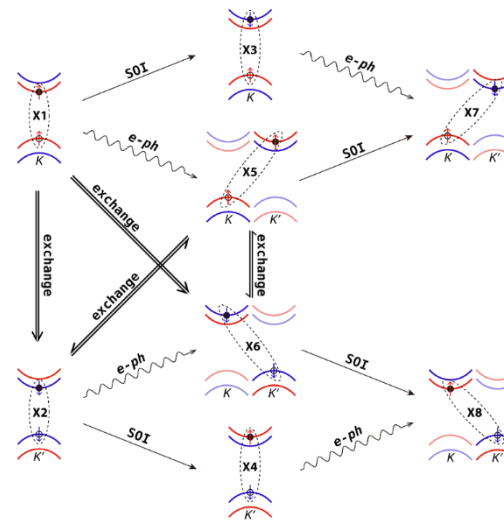


$$\text{Real-time - BSE}$$

$$i\hbar \frac{\partial \psi(r_e, r_h, t)}{\partial t} = \mathcal{H}(r; R) \psi(r_e, r_h, t)$$

two-particle

- ✓ Many-body interaction
- ✓ Exciton-phonon interaction
- ✓ Spin orbital coupling
- ✓ Nonadiabatic effects



Xiang Jiang
蒋翔

X. Jiang, Q. Zheng, Z. Lan, W. A. Saidi, X. Ren and J. Zhao* *Sci. Adv.*, **7**, eabf3759, (2021)


www.nature.com/natcomputsci / April 2021 Vol. 1 No. 4

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computational
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Protecting against racial
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research highlights

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TWO-DIMENSIONAL MATERIALS

Computationally probing exciton dynamics

Sci. Adv. **7**, eabf3759 (2021)

Light-matter interactions are essential to many optical and optoelectronic applications, such as solar-to-electrical energy conversion. When light sheds on a semiconductor material, an electron-hole (e-h) pair can be created. In semiconductor physics, a hole defines a

This team of researchers developed their computational method by integrating the ab initio non-adiabatic molecular dynamics (NAMD), the *GW* method, and real-time evolution of the Bethe-Salpeter equation (BSE); they named their method as *GW* + *rtBSE* + NAMD. In their framework,

Back ground

Single particle dynamics

Spin dynamics

Exciton Dynamics

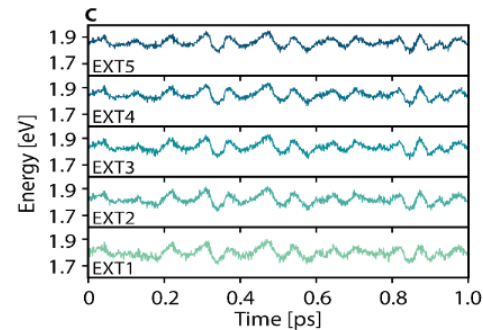
Outlook

What can be Done Using the GW-rtBSE NAMD Simulation

- ✓ Exciton Lifetime
- ✓ Hot exciton Relaxation
- ✓ Exciton transition
at interface
via spin valley
bright-to-dark
- ...
- ✓ Exciton-Phonon Interaction
- ✓ Exciton-Polaron interaction

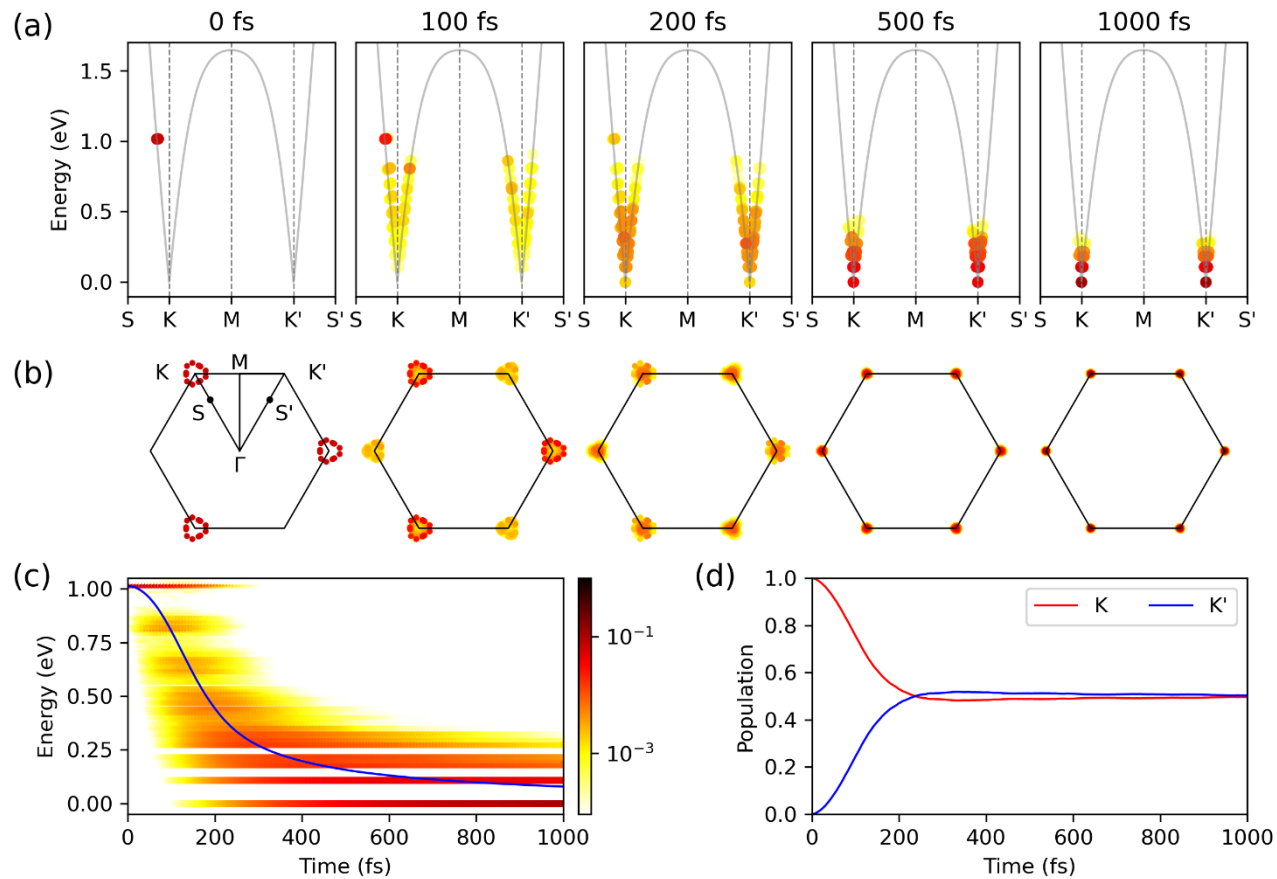
✓ Excited state potential surface
from machine learning

Photo-induced phase transition
Photocatalysis

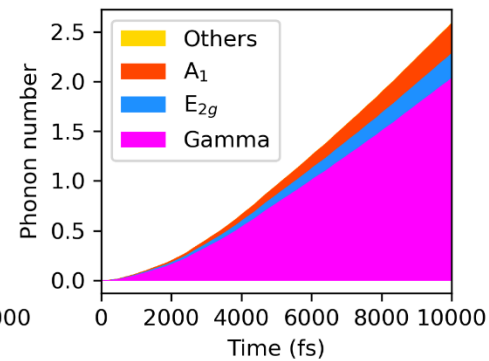
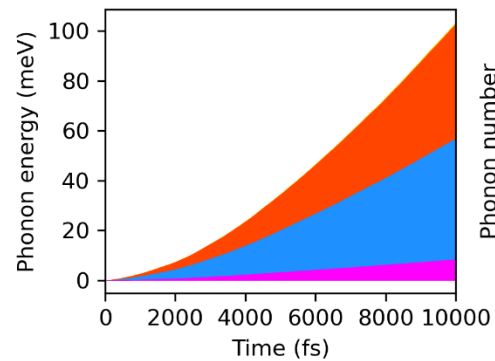
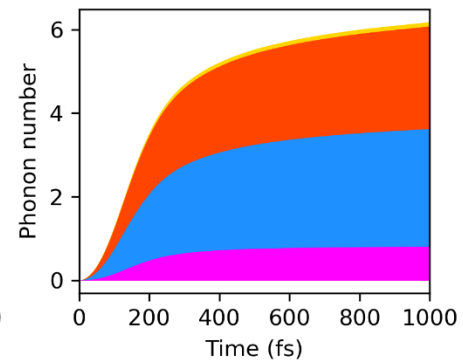
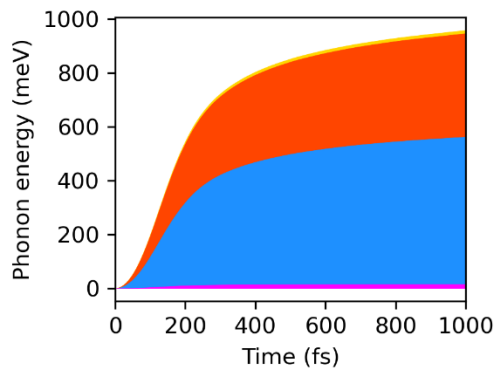
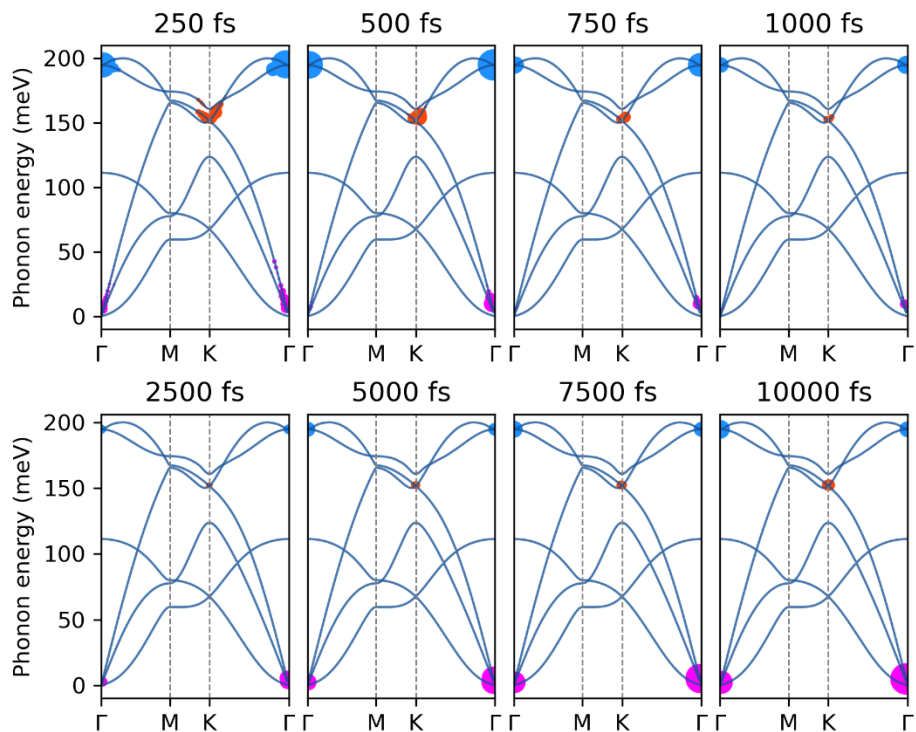


Several thousands of exciton energies
can be used for machine learning

NAMD Simulation in Momentum Space

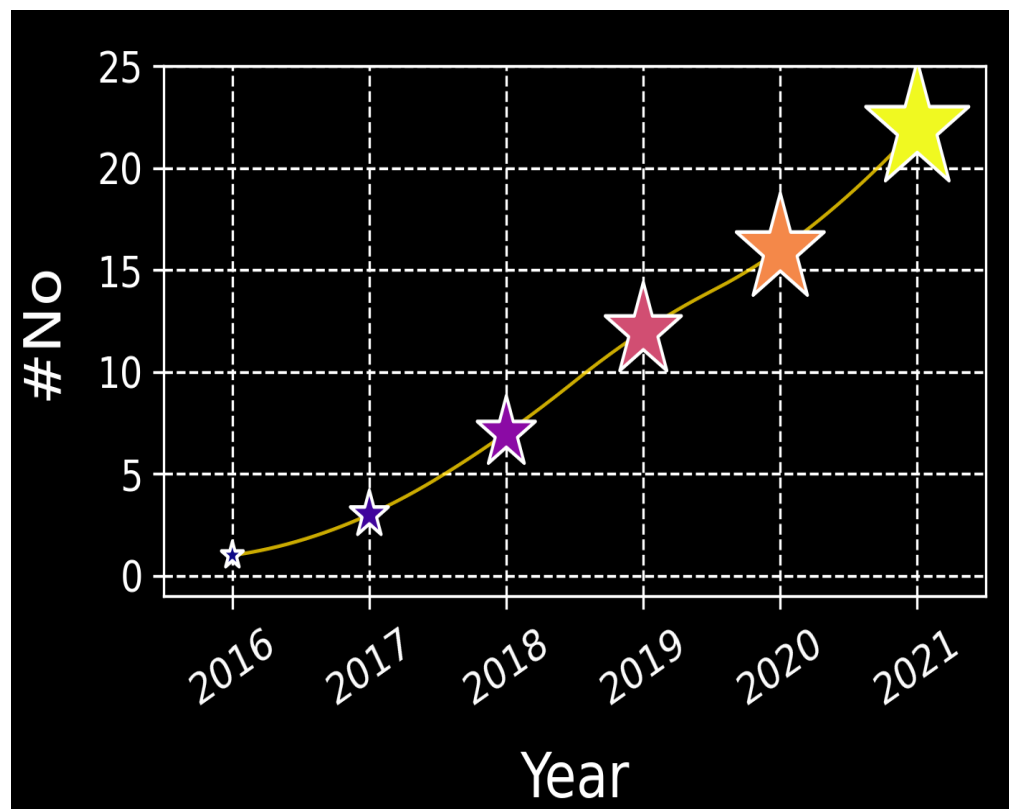


Phonon Excitation



Hefei-NAMD的应用与推广

Publications by Hefei-NAMD (over 80)



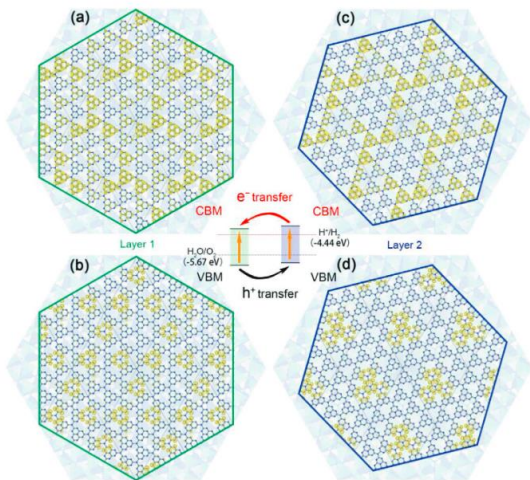
Journal	Number of Publications
Sci. Adv.	3
Nat. Commun.	1
Phys. Rev. Lett.	3
JACS	2
Adv. Mater.	1
Nano Lett.	4
ACS NANO	1
J. Phys. Chem. Lett.	18
Chem. Sci.	1
Angew Chem.	1

Ultrafast Interlayer Charge Separation, Enhanced Visible-Light Absorption, and Tunable Overpotential in Twisted Graphitic Carbon Nitride Bilayers for Water Splitting

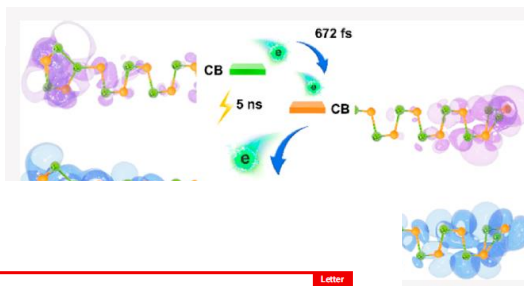
Xirui Zhang, Tong Wu, Chao Yu, and Ruifeng Lu*

Universal Zigzag Edge Reconstruction of an α -Phase Puckered Monolayer and Its Resulting Robust Spatial Charge Separation

Yanxue Zhang, Yanyan Zhao, Yizhen Bai, Junfeng Gao,* Jijun Zhao, and Yong-Wei Zhang*



南京理工大学陆瑞峰



大连理工大学高峻峰

Two Dimensional MOene: From Superconductors to Direct Semiconductors and Weyl Fermions

Luo Yan, Jiaojiao Zhu, Bao-Tian Wang, Junjie He, Hai-Zhi Song, Weibin Chu, Sergei Tretjak, and Liujiang Zhou*

Cite This: <https://doi.org/10.1021/acs.nanolett.2c01914>

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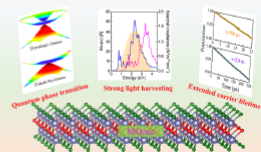
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Article Recommendations

Supporting Information

ABSTRACT: The number of semiconducting MXenes with direct band gaps is extremely low; thus, it is highly desirable to broaden the MXene family beyond carbides and nitrides to expand the palette of desired chemical and physical properties. Here, we theoretically report the existence of the single-layer (SL) dinitium oxide 2H-Ti₂O MOene (MXene-like 2D transition oxides), showing an intriguing superconducting feature. Moreover, SL halogenated 2H- and 1T-Ti₂O monolayers display tunable semiconducting features and strong light-harvesting ability. In addition, the external strains can induce Weyl fermions via quantum phase transition in 2H-Ti₂O₂F₂ and Ti₂OCl₂ monolayers. Specifically, 2H- and 1T-Ti₂O₂F₂ are direct semiconductors with band gaps of 0.82 and 1.18 eV, respectively. Furthermore, the carrier lifetimes of SL 2H- and 1T-Ti₂O₂F₂ are evaluated to be 0.39 and 2.8 ns, respectively. This study extends emerging phenomena in a rich family of 2D MXene-like MOene materials, which provides a novel platform for next-generation optoelectronic and photovoltaic fields.

KEYWORDS: MXene-like MOene, halogenation, quantum phase transition, exciton, nonadiabatic molecular dynamics



电子科大周柳江

Reference & Developers

Video

Hefei-NAMD使用的一些经验

<https://www.koushare.com/video/videodetail/11720>

Hefei-NAMD基本流程介绍

<https://www.bilibili.com/video/BV1p5411c7RS>

Hefei-NAMD培训

<https://www.koushare.com/lives/room/341102>

Website:

<http://staff.ustc.edu.cn/~zqj>

<http://staff.ustc.edu.cn/~zhaojin>

<https://github.com/QijingZheng>

<https://github.com/WeibinChu>

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Dr. Chuanyu Zhao (赵传寓), zhaochuanyu@zju.edu.cn, DISH

Mr. Zhenfa Zheng (郑镇法), zzfgjs@mail.ustc.edu.cn, Dynamics in momentum space

Determining Factors of Carrier Dynamics

No perturbation, no relaxation : $\langle \psi_i | \psi_j \rangle = 0$

With perturbation:

$$\langle \psi_i | B | \psi_i \rangle$$

Magnetic field induced spin dynamics

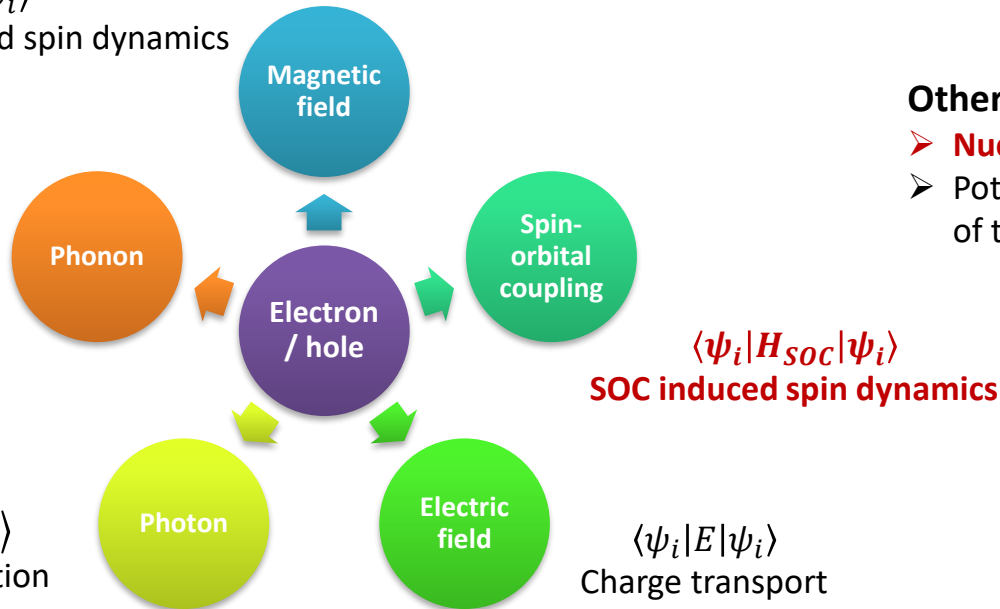
$$\langle \psi_i | \frac{\partial}{\partial t} | \psi_i \rangle$$

$$\langle \psi_{nk} | \Delta V | \psi_{n'k'} \rangle$$

Nonradiative relaxation

$$\langle \psi_i | E e^{i\omega t} | \psi_i \rangle$$

Radiative relaxation



$$\langle \psi_i | E | \psi_i \rangle$$

Charge transport

Many-body effects:

- e-e interaction
- **e-h interaction (exciton effects)**
- spin-spin interaction

Other effects:

- **Nuclear quantum effects**
- Potential energy surface of the excited state



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博士生



史永亮
华为



张丽丽
郑州大学讲师



赵传寓
腾讯



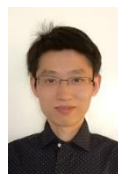
兰峥岗
华南师大
Surface hopping



李新征
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PIMD



任新国
中科院物理所
GW+BSE



谭世惊
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实验



王兵
中科大
实验



Hrvoje Petek
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实验



杨金龙
中科大
讨论+支持

感谢基金委、科技部、中国科大的经费支持